

Latest developments and characterisation results of the MALTA sensors in TowerJazz 180nm for High Luminosity LHC

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Andrea Gabrielli
CERN

12th International Conference on
**POSITION SENSITIVE
DETECTORS**



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MALTA Single Chip Testboard

CMOS motivation

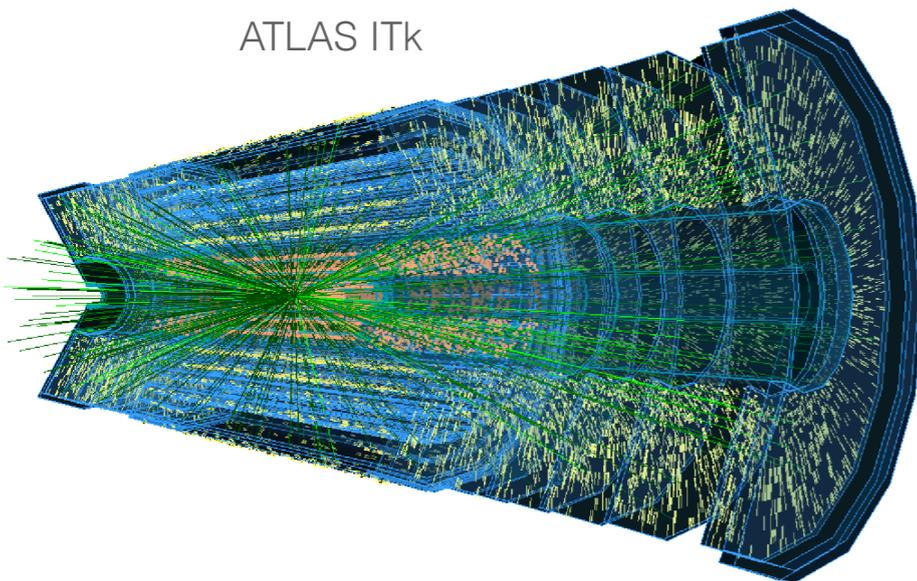
- requirements for future HEP detectors are very challenging:
 - extreme radiation tolerance
 - very fast response
 - very large surface
 - very thin
 - high granularity

CERN-OPEN-2018-006

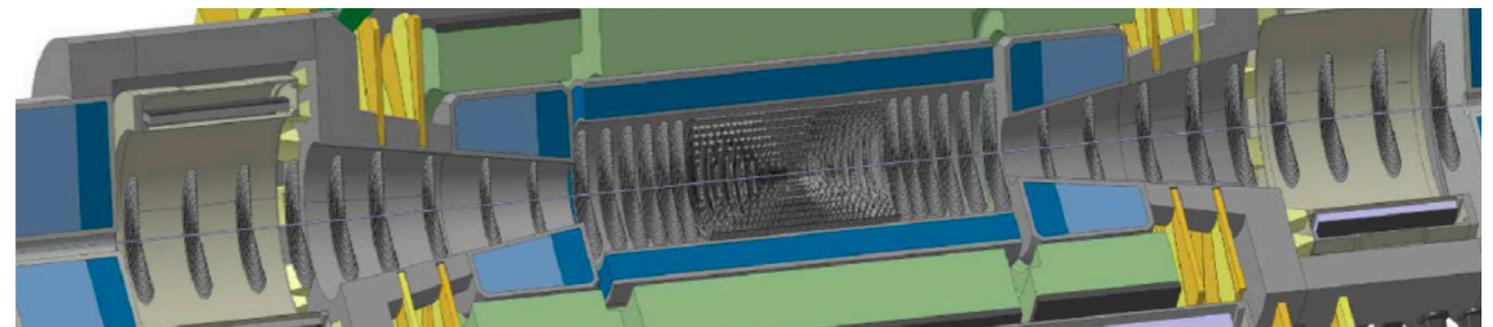
Parameter \ Exp.	LHC	HL-LHC	SPS	FCC-hh	FCC-ee	CLIC 3 TeV
Fluence [$n_{eq}/cm^2/y$]	$N \times 10^{15}$	10^{16}	10^{17}	$10^{16} - 10^{17}$	$<10^{10}$	$<10^{11}$
Max. hit rate [$s^{-1}cm^{-2}$]	100 M	2-4 G****)	8 G****)	20 G	20 M****)	240k
Surface inner tracker [m^2]	2	10	0.2	15	1	1
Surface outer tracker [m^2]	200	200	-	400	200	140
Material budget per detection layer [X_0]	0.3%*) - 2%	0.1%*) - 2%	2%	1%	0.3%	0.2%
Pixel size inner layers [μm^2]	100x150-50x400	$\sim 50 \times 50$	$\sim 50 \times 50$	25x50	25x25	$< \sim 25 \times 25$
BC spacing [ns]	25	25	$>10^9$	25	20-3400	0.5
Hit time resolution [ns]	$< \sim 25 - 1k^*$)	$0.2^{**}) - 1k^*$)	0.04	$\sim 10^{-2}$	$\sim 1k^{***})$	~ 5

*) ALICE requirement ***) LHCb requirement ****) At Z-pole running *****) max. output rate for LHCb/high intensity flavour experiments: 300-400 Gbit/s/cm²

ATLAS ITk

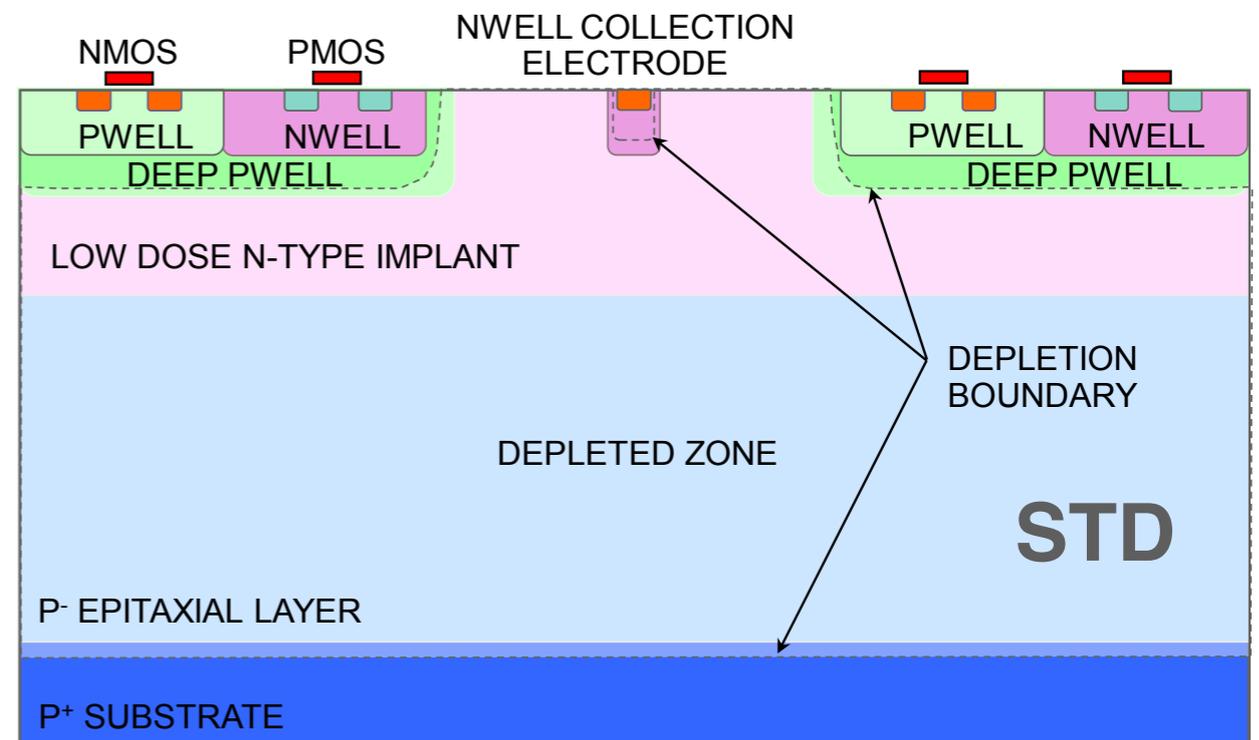
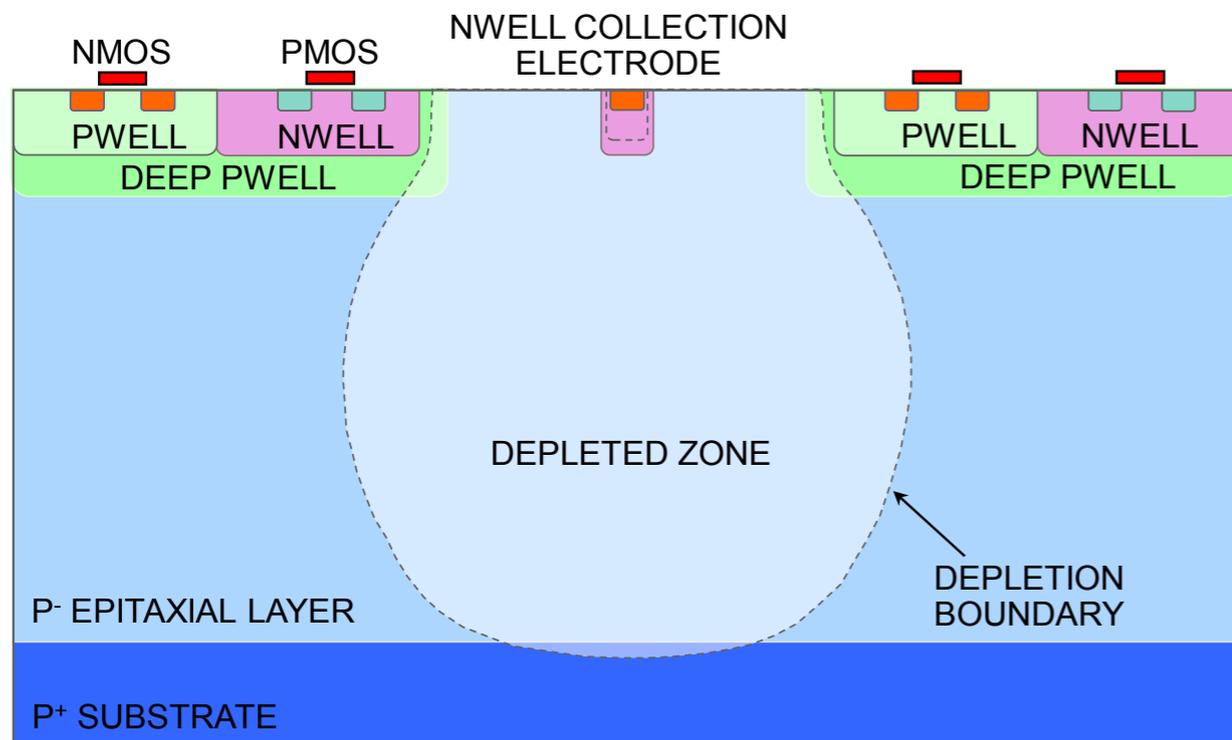


FCC: hh



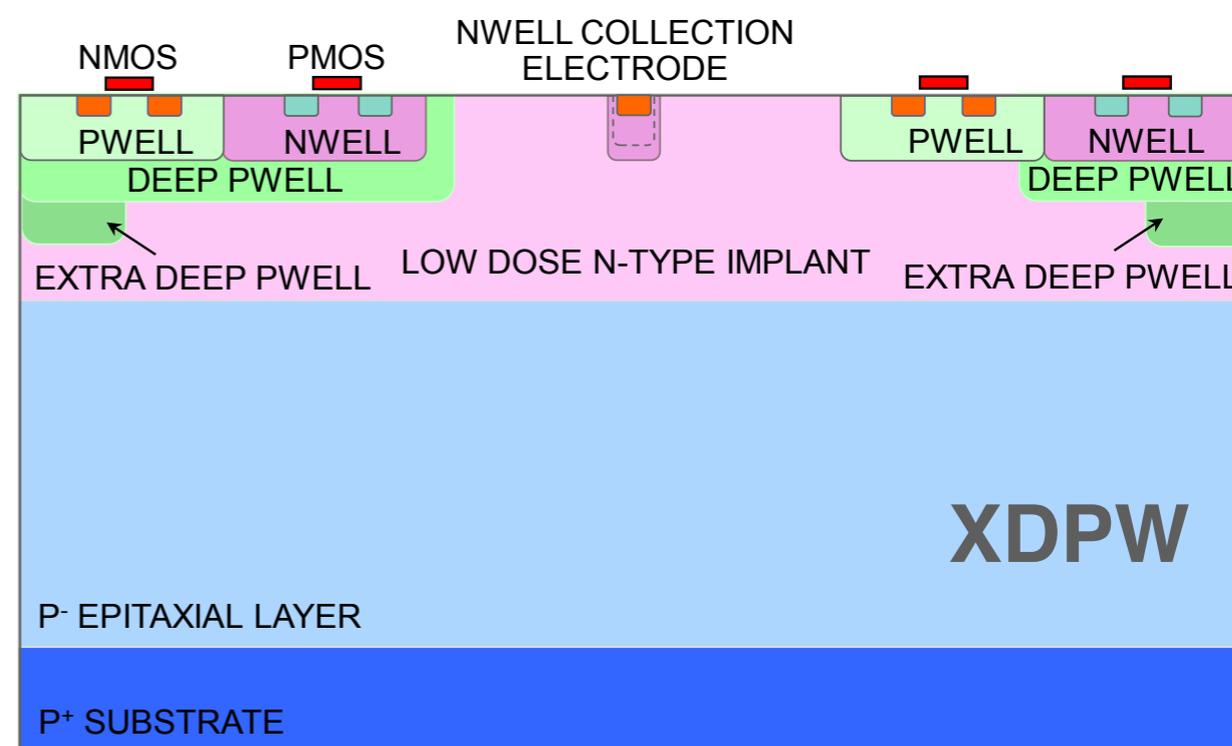
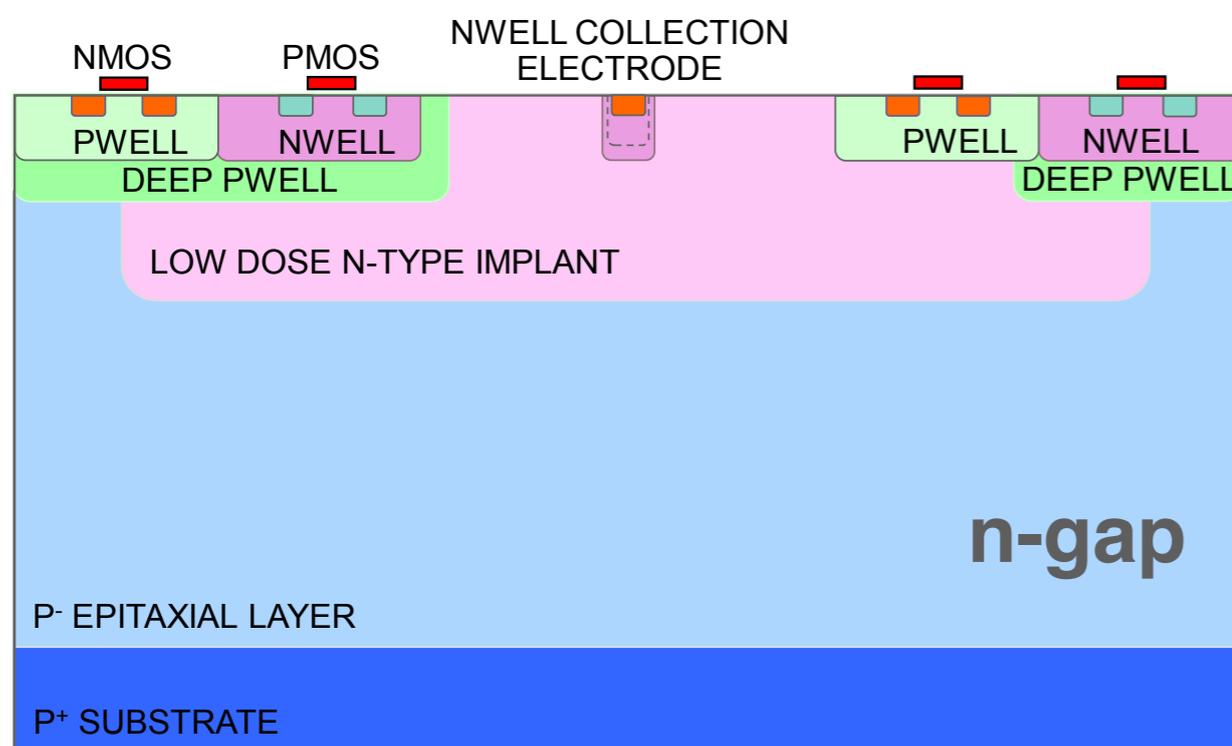
Tower Semiconductor 180nm CMOS sensors

- Towerjazz process:
 - high-resistivity Epi layer, 25 μm depletion \rightarrow ~ 1500 e- for MIP, high signal to noise ratio (~ 20)
- modified process:
 - extra low dose n-type layer to improve depletion under the deep p-well, better radiation tolerance



Tower Semiconductor 180nm CMOS sensors

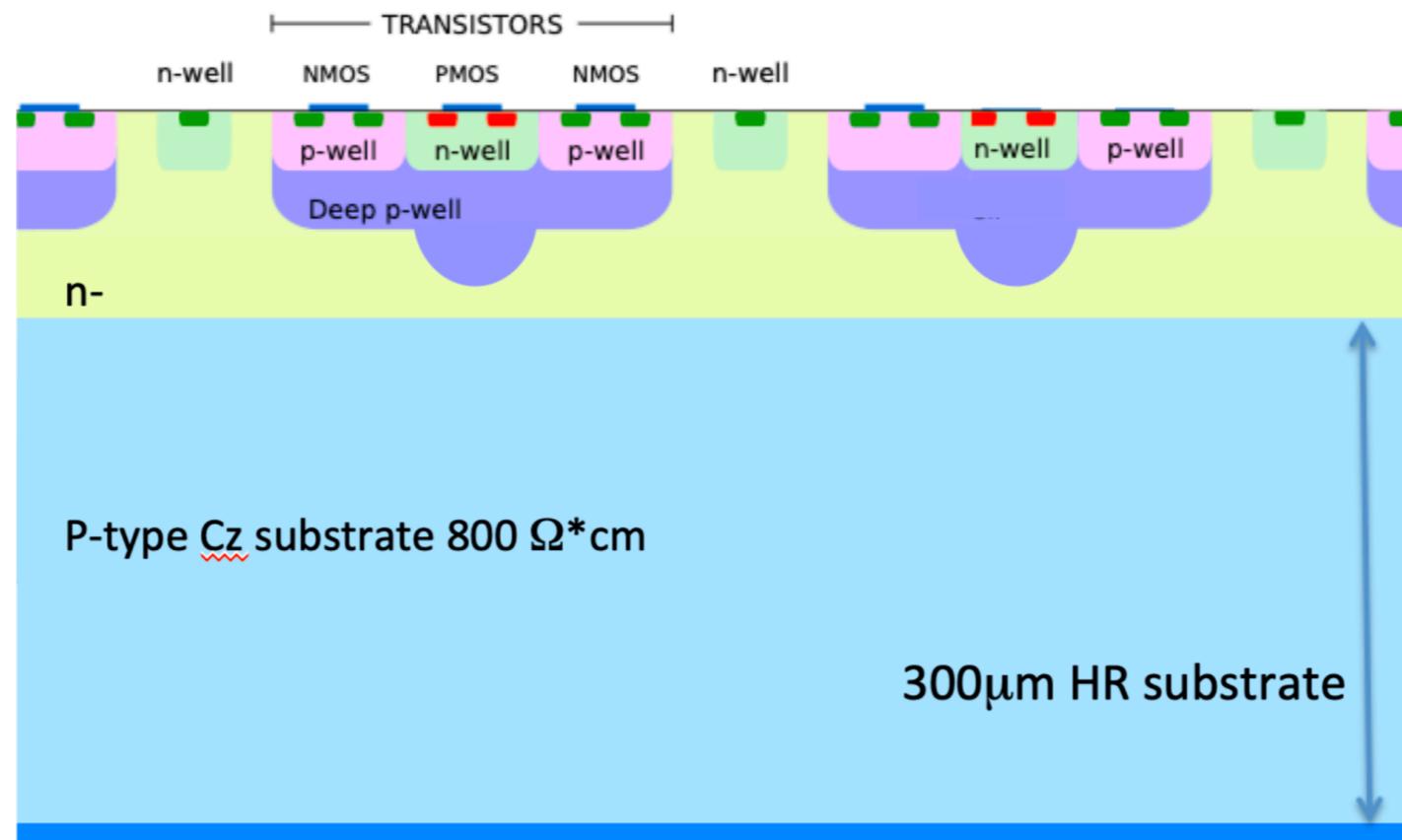
- special layouts for deep p and n wells to optimize field configuration and charge collection: increase lateral field near pixel edge to “focus” charge to electrode:
 - gap in the n-layer: 4 μm gap in the low dose n-layer
 - ‘extra-deep p-well’ layer: 5 μm wide additional p-well implant



H.Pernegger NIM A 986 (2021) 164381
M. Dyndal, JINST 15 (2020) P02005
M. Mironova, NIM A 956 (2020) 163381
Magdalena, M.Munker PIXEL 2018

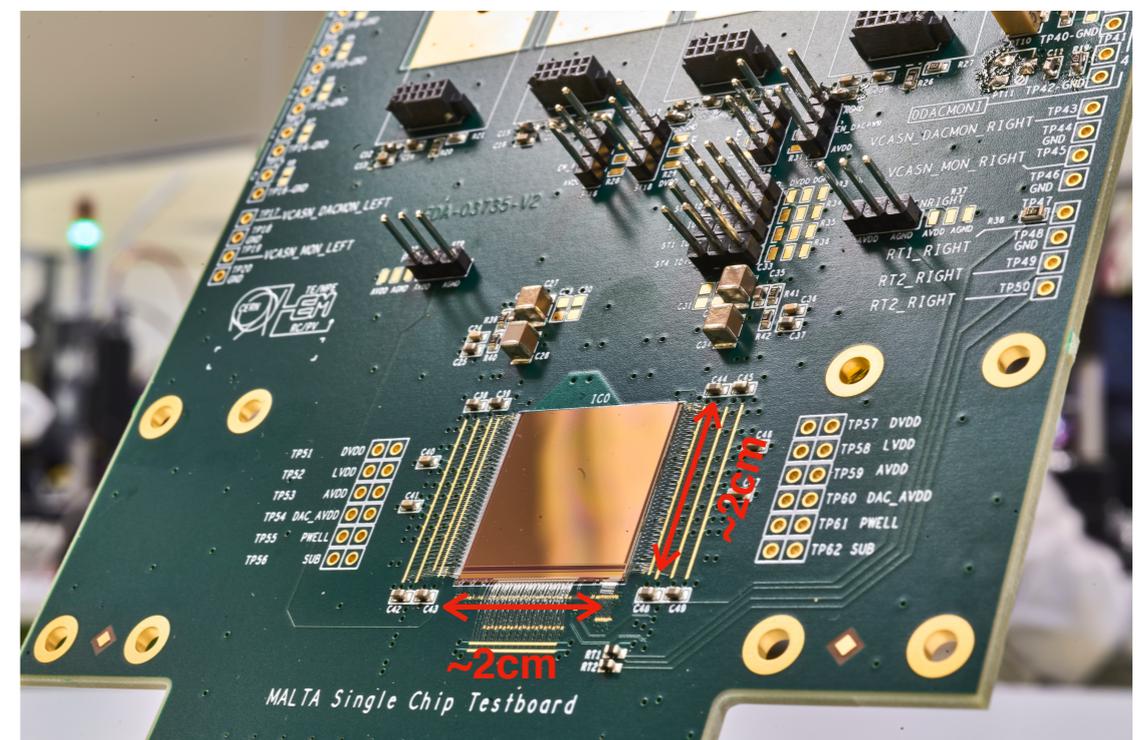
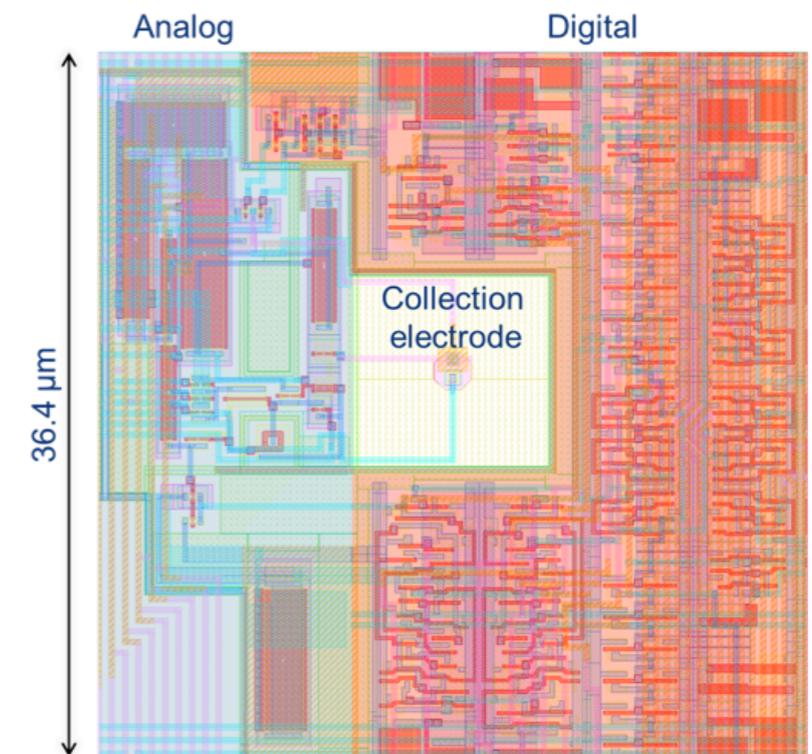
Tower Semiconductor 180nm CMOS sensors

- MALTA with high resistivity Czochralski(Cz) substrate material
- significant larger depletion and signal:
 - higher radiation hardness
 - high operation voltage up to 50V -> high depletion depth



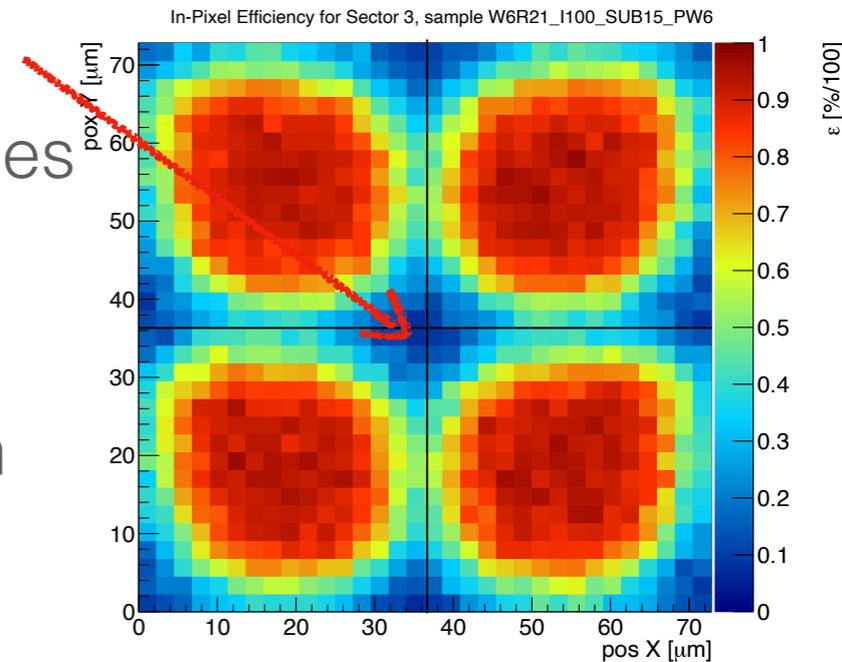
MALTA pixel detector

- matrix 512 x 512 pixels of $36.4 \times 36.4 \mu\text{m}^2$ size
- small collection electrode of $2\text{-}3 \mu\text{m}^2$ to achieve minimal input capacitance $<3\text{fF}$
- $3.4\text{-}4 \mu\text{m}$ spacing between electrode and electronics: low cross talk
- asynchronous architecture
- very low power consumption:
 - $1 \mu\text{W}/\text{pixel}$ analog power
 - $70 \text{ mW}/\text{cm}^2$ analog power
 - $10 \text{ mW}/\text{cm}^2$ digital power
- parallel read-out bus 37bit
- Xilinx Virtex/Kintex FPGA for readout

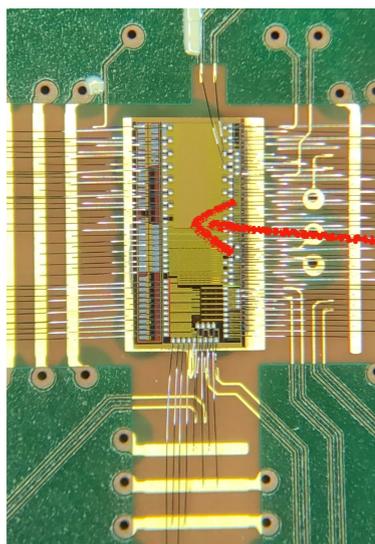


Malta history

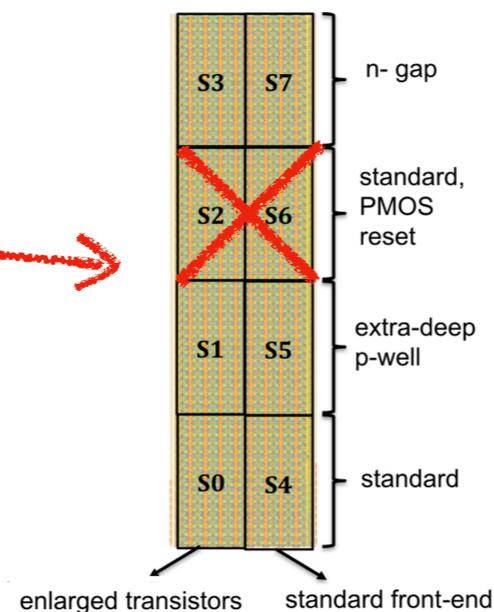
- 2018, first MALTA: after neutron irradiation the collection efficiency is degraded at pixel edges
- Jan 2019, MiniMALTA: smaller matrix version that changes the p-well extension to address the efficiency loss on corners and improved Front-End
- Aug 2019, reprocessed MALTA: large demonstrator with MiniMalta sensor improvements
- Jan 2021: MALTA2 improved Front-End



MiniMALTA demonstrator
5 mm x 1.7 mm



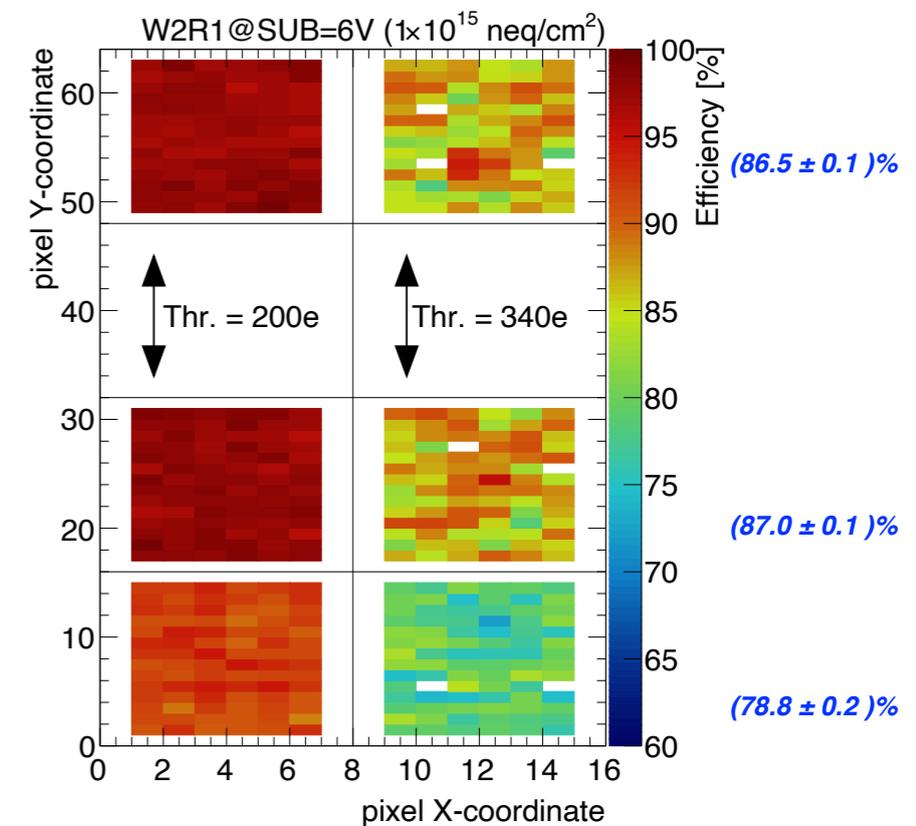
JINST 15 (2020) 02, P02005
I. Asensi VERTEX (2020)



(97.6 ± 0.1)%

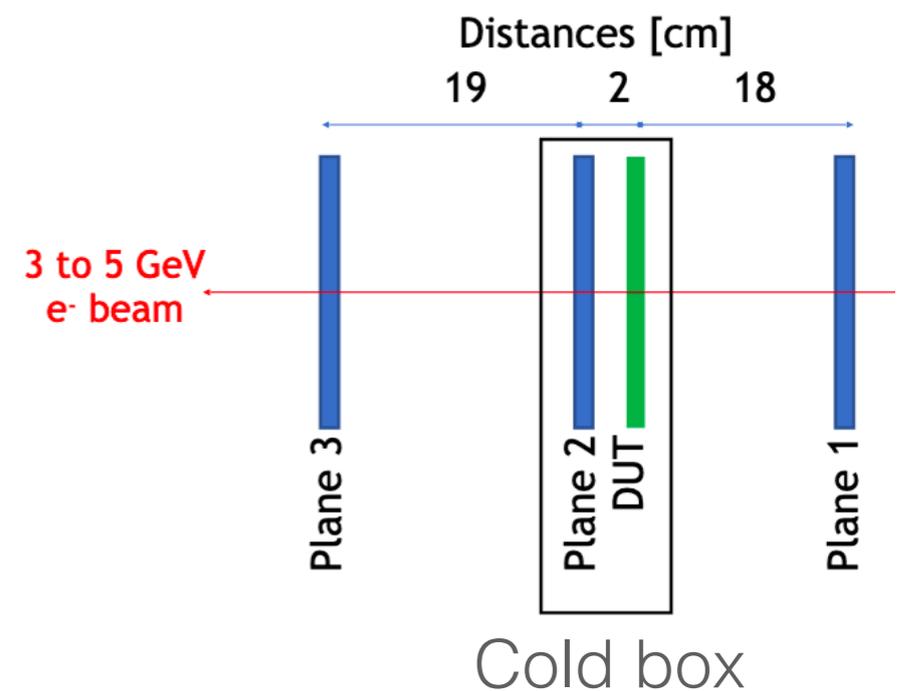
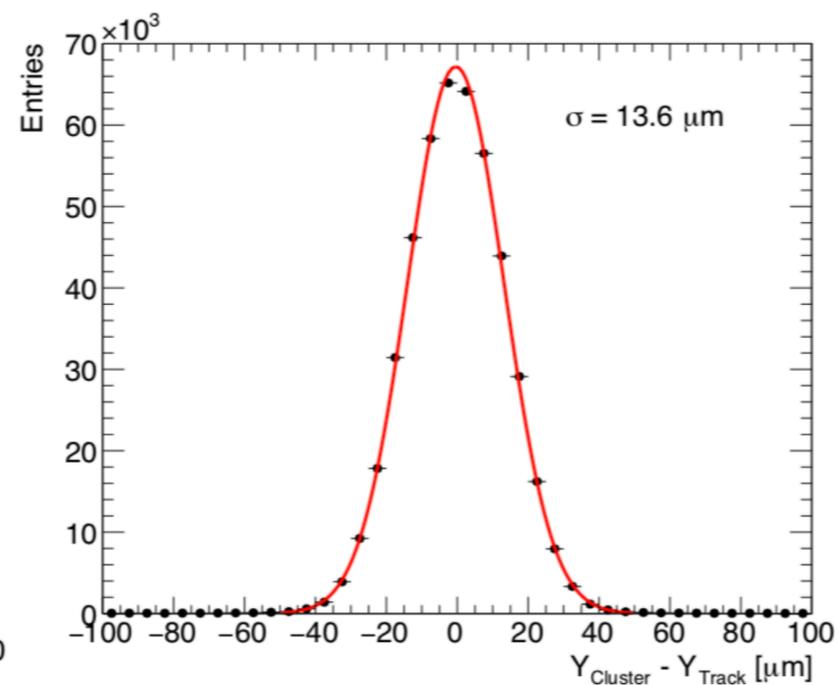
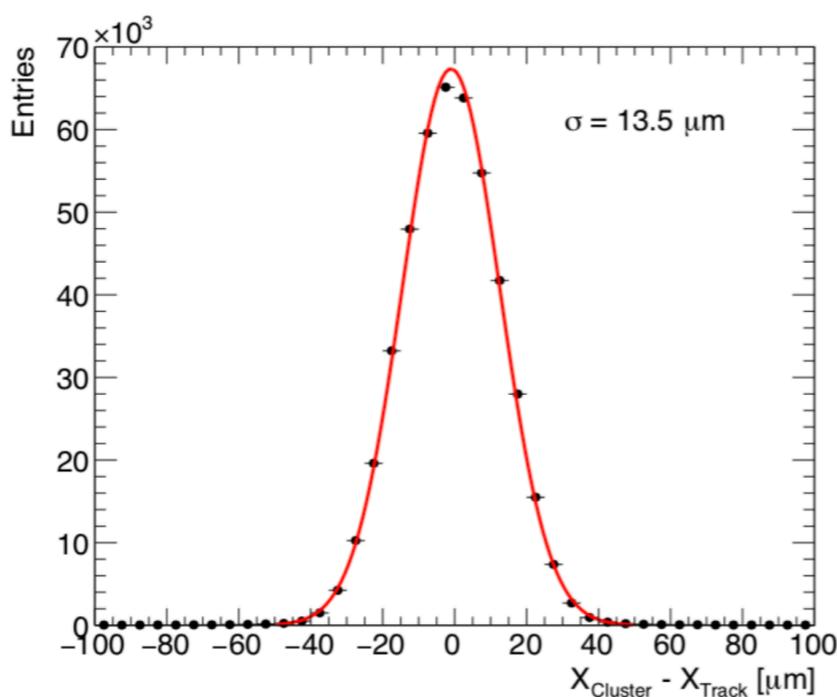
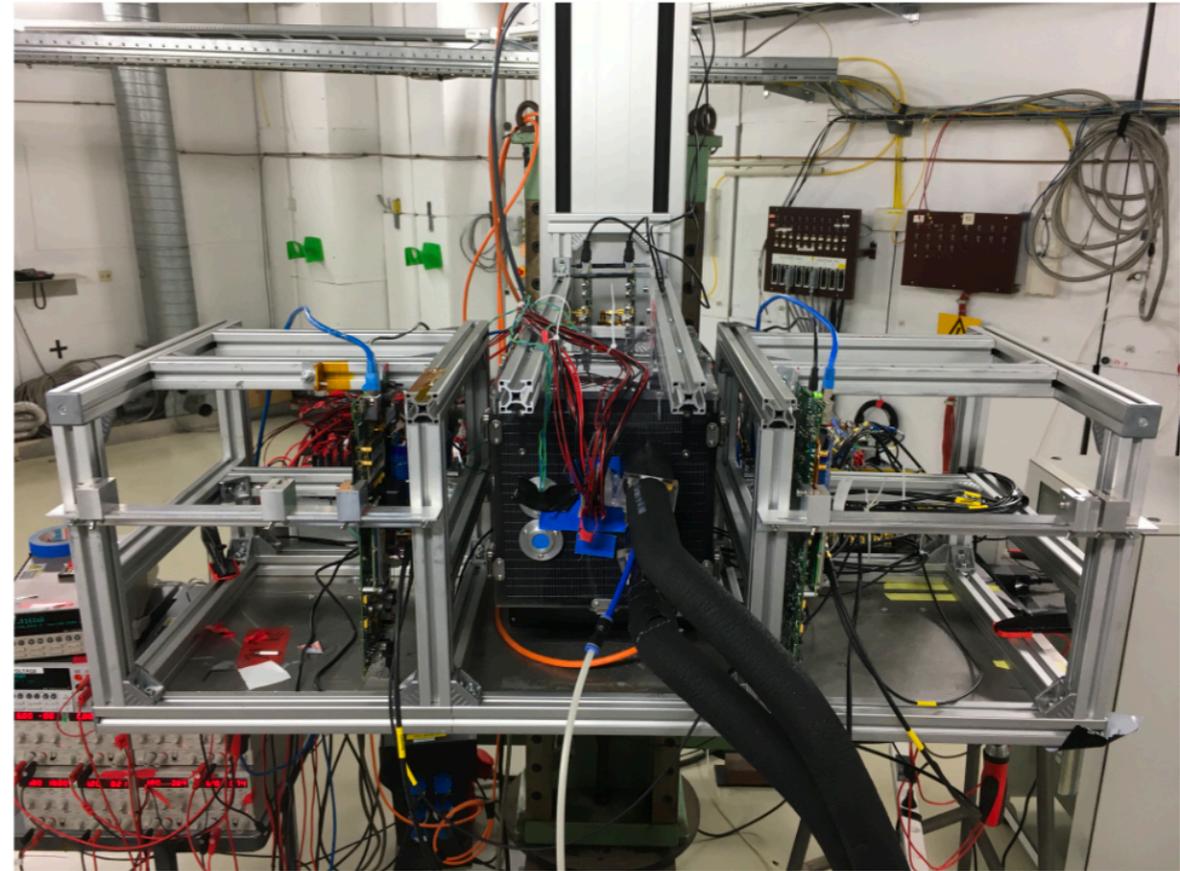
(97.9 ± 0.1)%

(91.9 ± 0.1)%



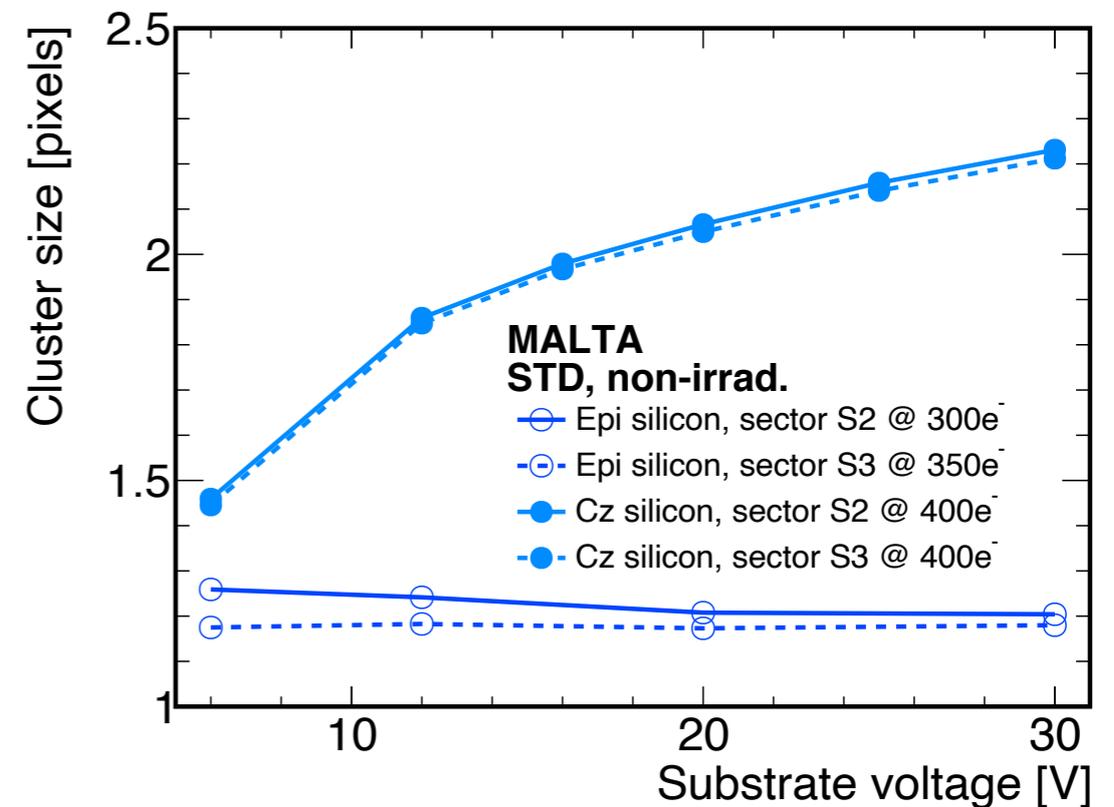
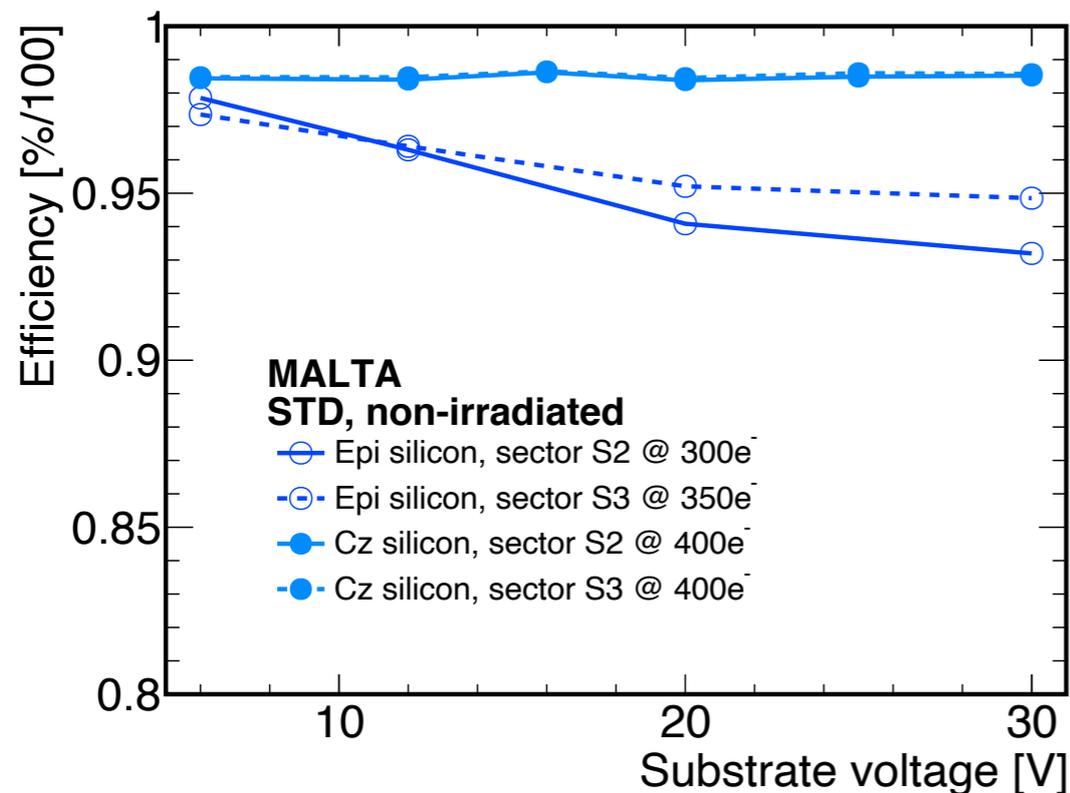
MALTA telescope testbeam

- DESY testbeam energy = 3-4 GeV
- custom MALTA-based telescope
 - up to 7 MALTA tracking planes (100 μm thick, 36 μm pitch size)
 - triggering on planes with custom TLU with high flexibility
 - tracking performance $\sim 13 \mu\text{m}$ residual width



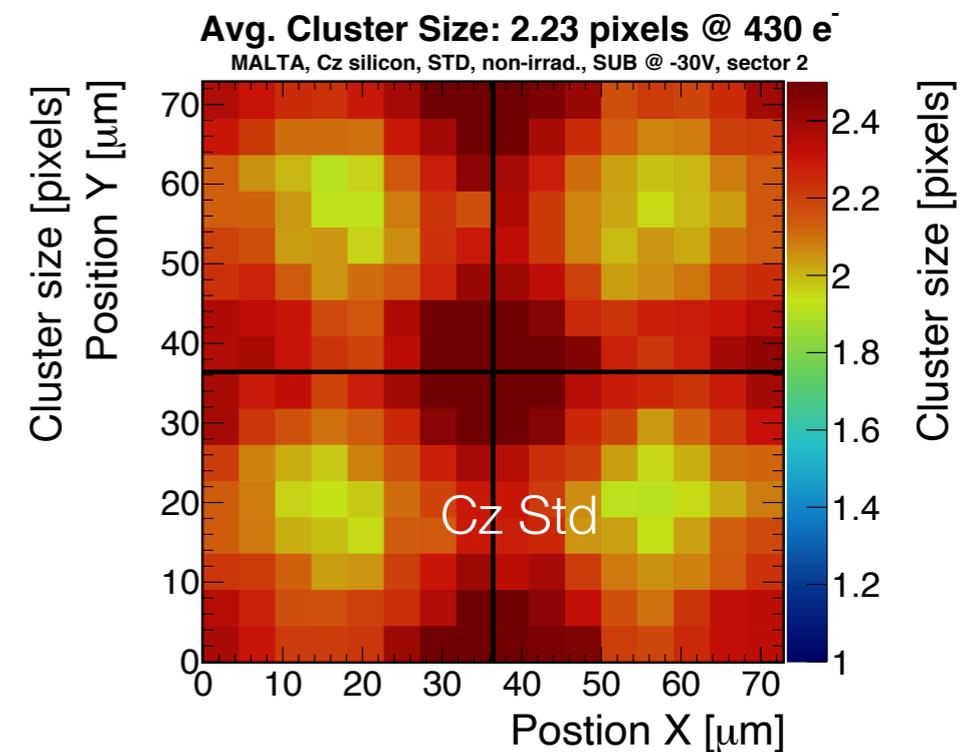
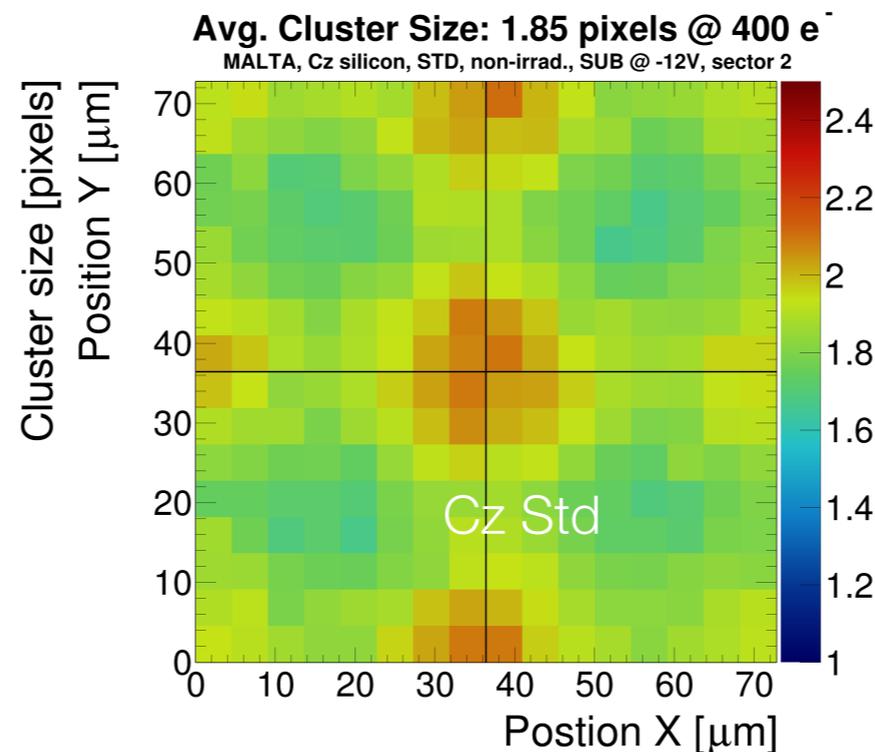
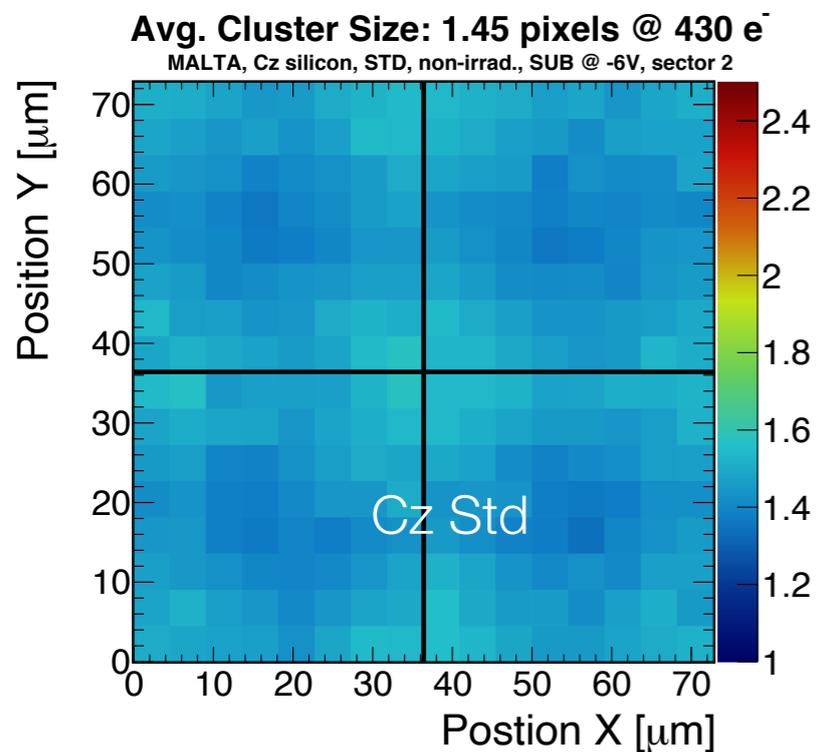
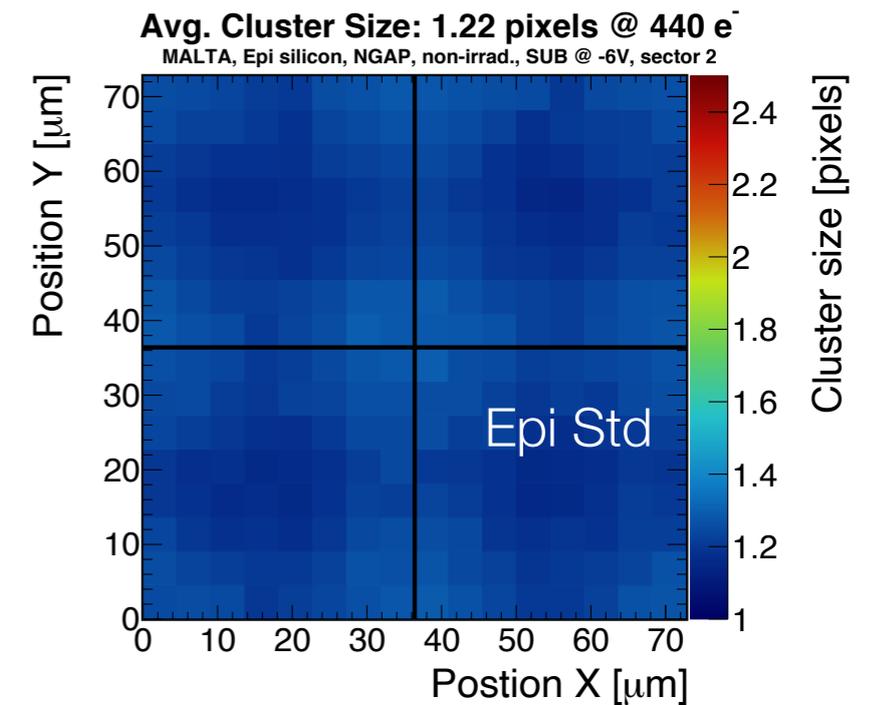
MALTA non-irradiated chip

- efficiency vs substrate voltage:
 - Epi: no gain at high voltage (full depletion at 6V)
 - Cz: flat efficiency vs substrate voltage
- cluster size vs substrate voltage:
 - Epi: constant cluster size
 - Cz: smooth increase when increasing substrate voltage (more charge sharing in Cz material)



MALTA non-irradiated chip

- in-pixel cluster size vs substrate voltage (shown as 2x2 pixel x-y dependency)
- Cz has larger cluster size and more charge collection sharing



6 V

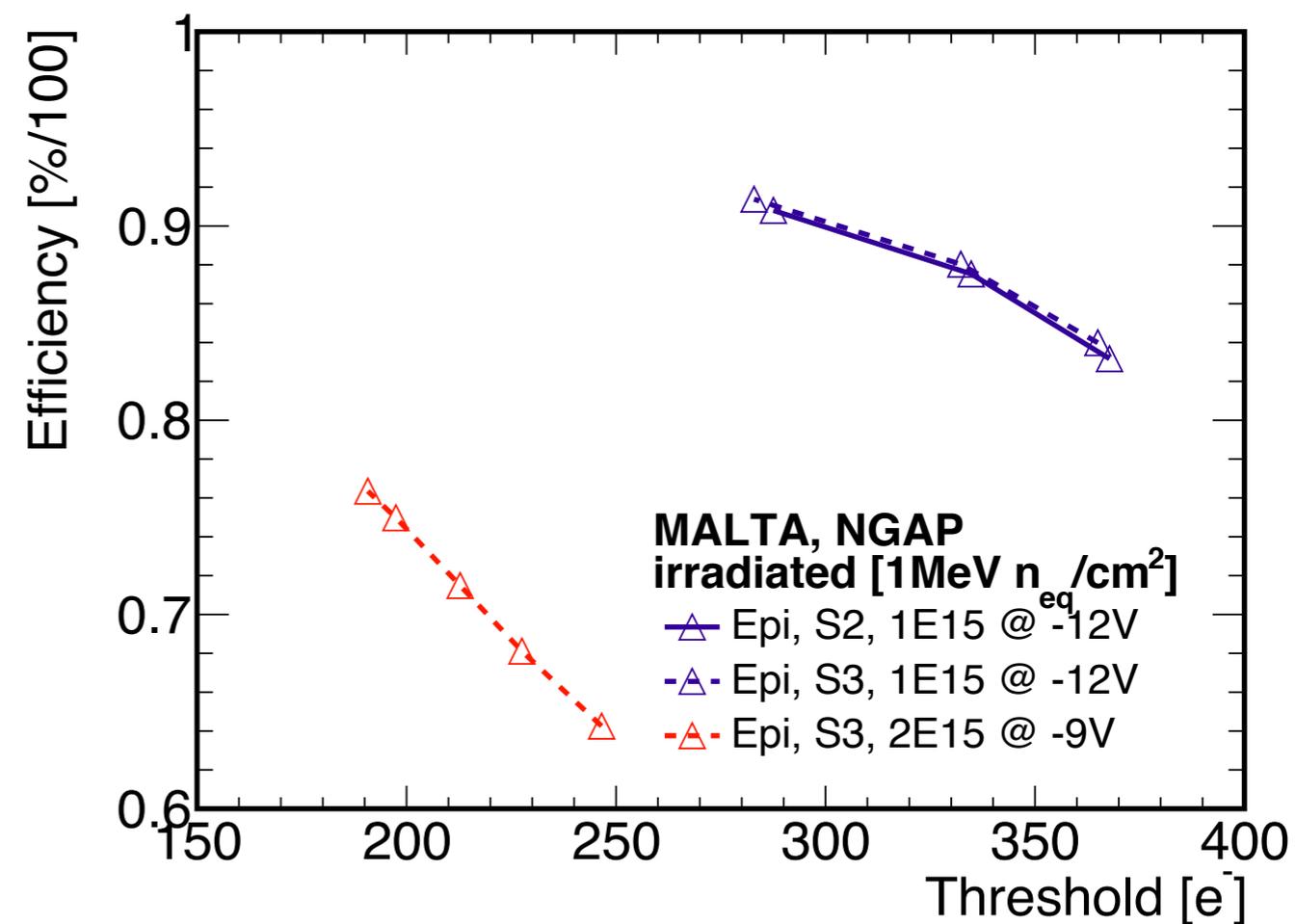
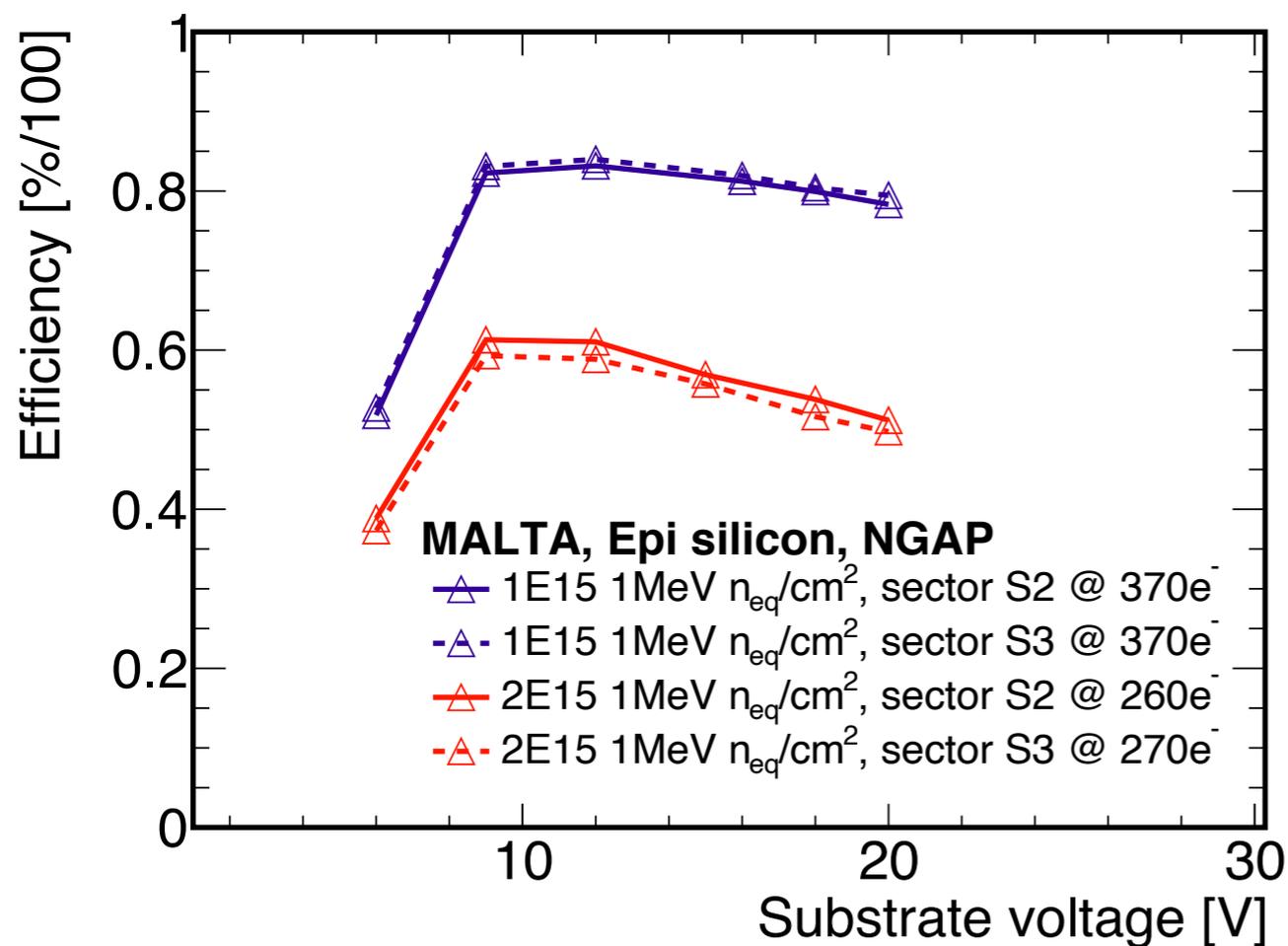
12 V

30 V

SUB V

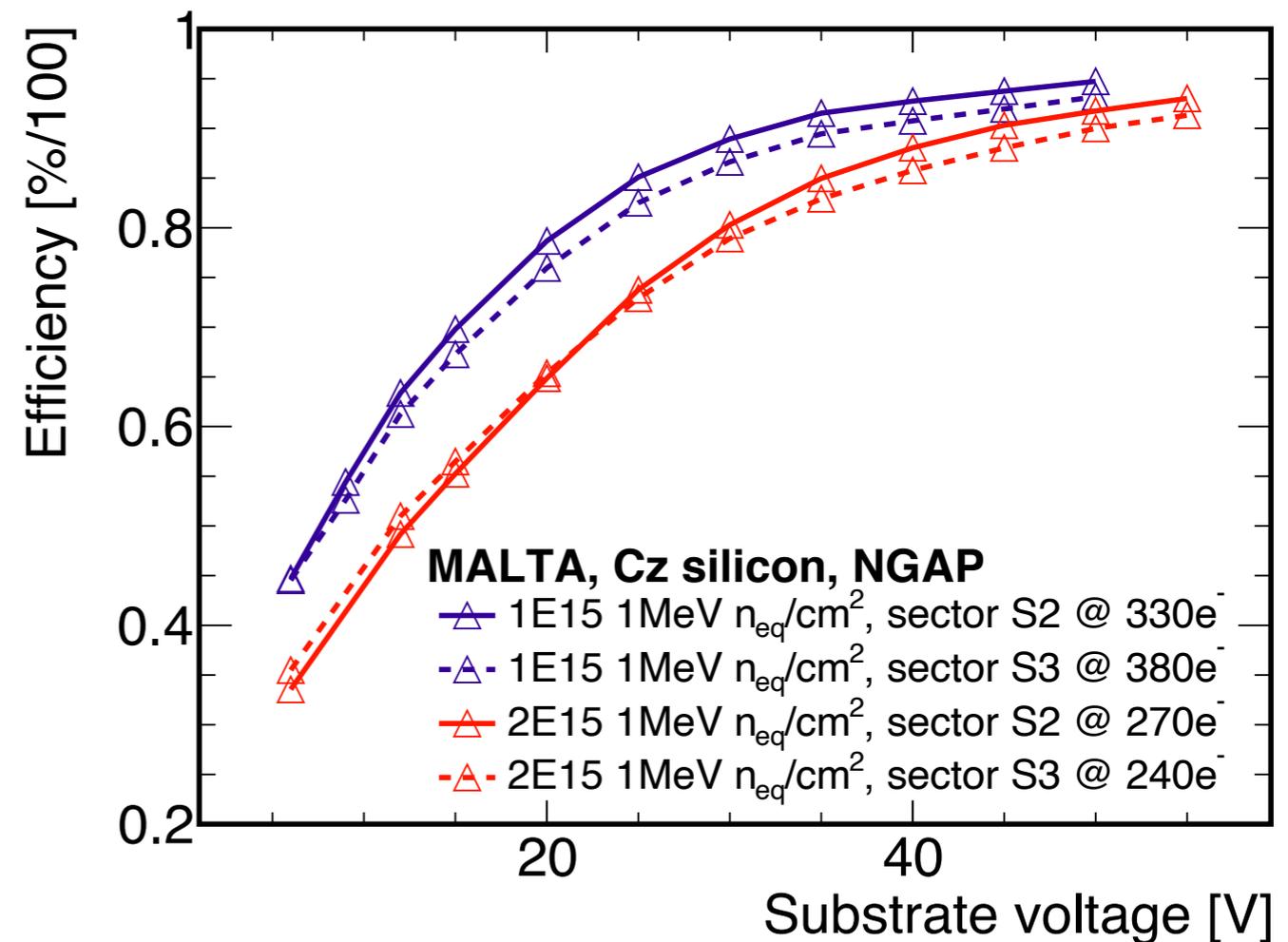
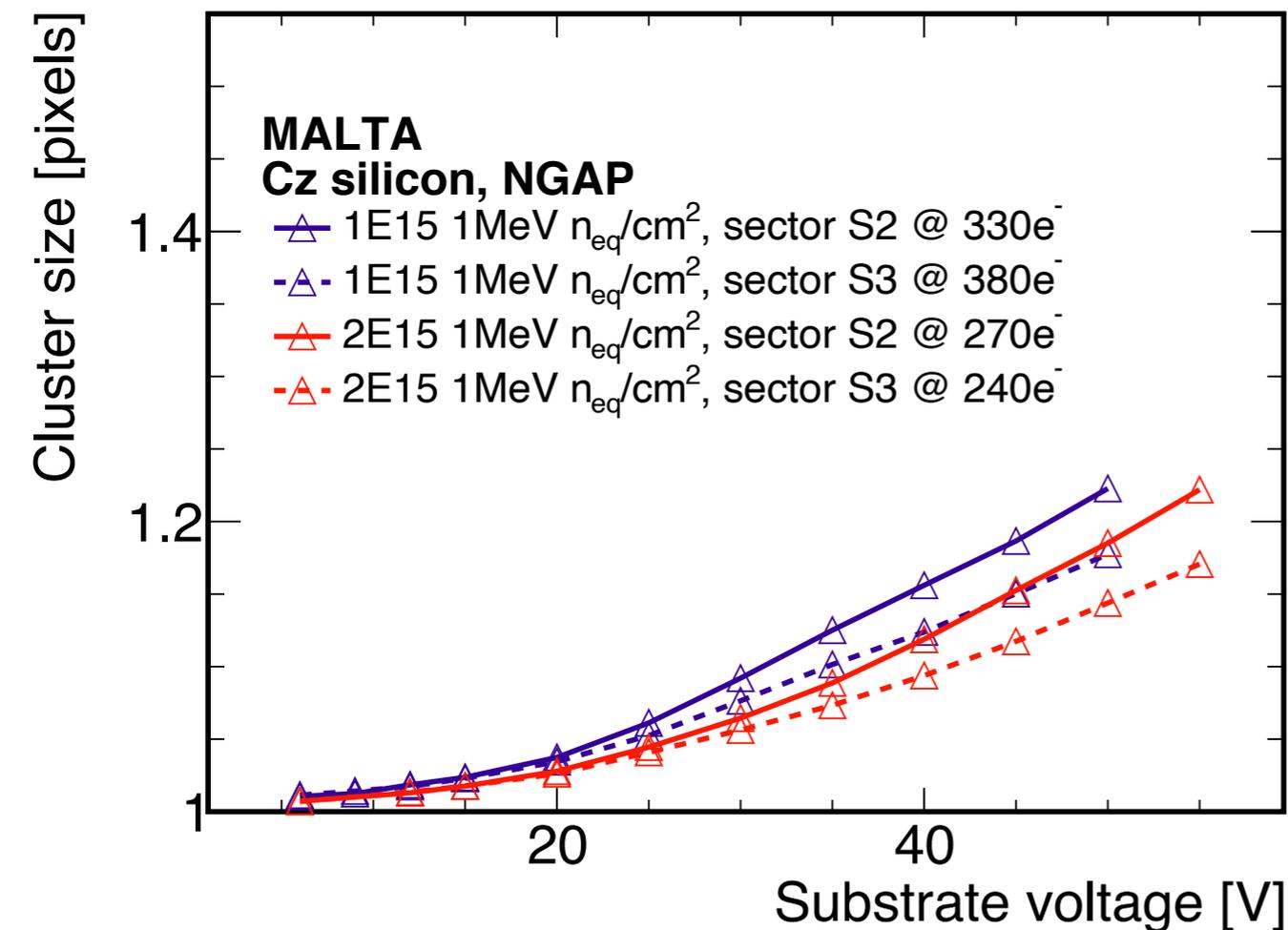
MALTA irradiated chips

- Epi silicon sensor low efficiency for irradiated chip ($1e^{15} n_{eq}/cm^2$)
~80% @ -10 V @ 370 e⁻
- no gain with higher substrate voltage
- results consistent with previous MiniMalta measurements



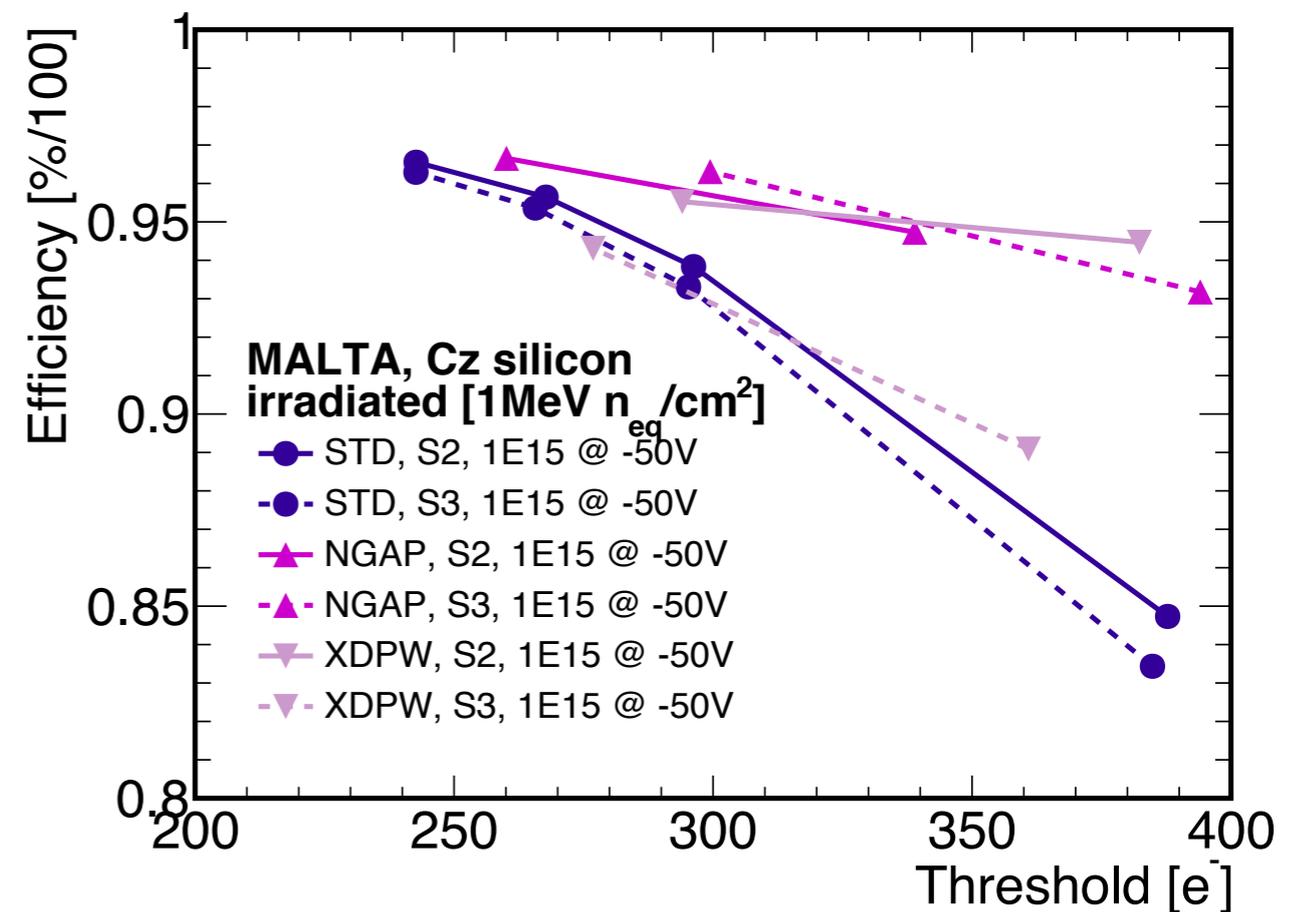
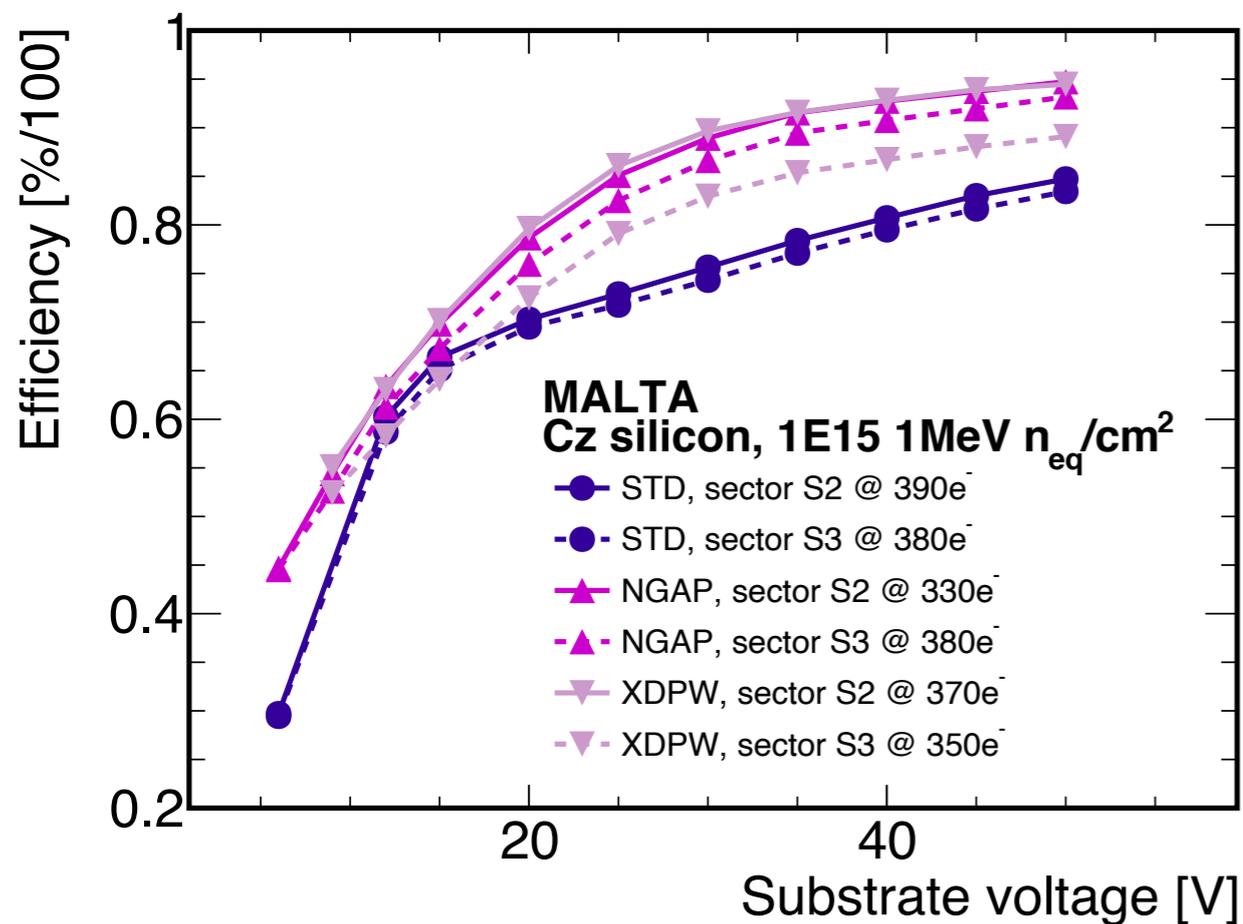
MALTA irradiated chips

- Cz silicon sensor: higher radiation hardness
- smooth dependency of efficiency (and cluster size) vs substrate voltage
- max efficiency with irradiated chip (n-gap @ $2e^{15} n_{eq}/cm^2$) $\sim 93\%$



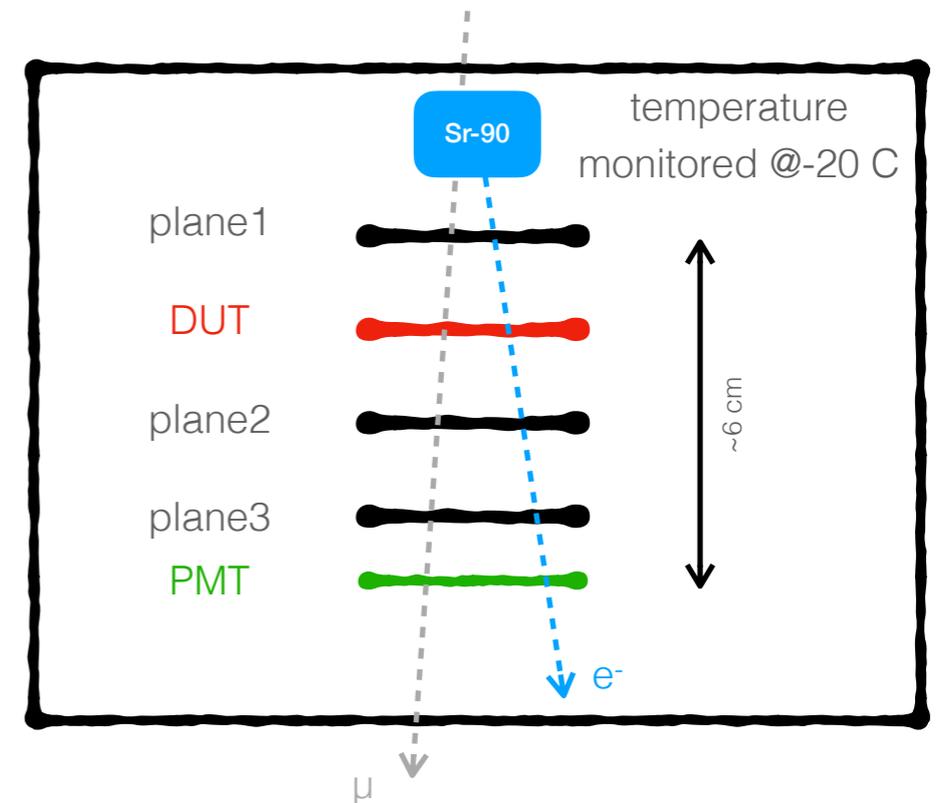
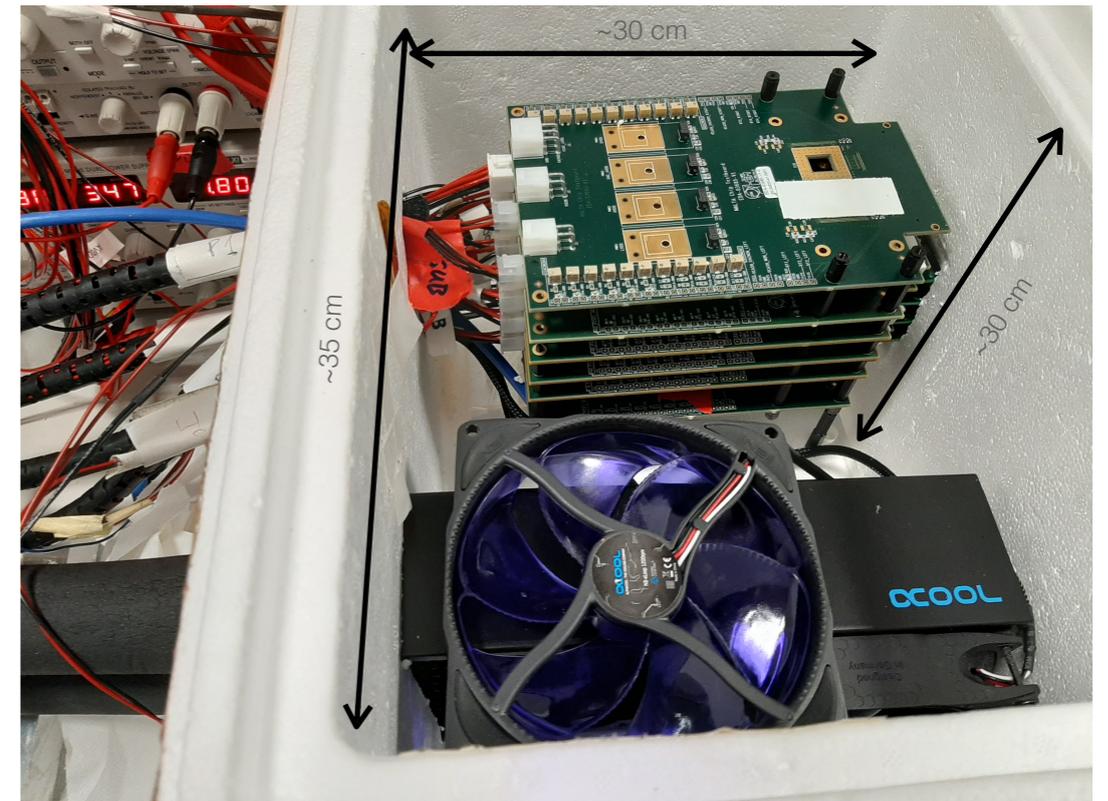
MALTA irradiated chips

- Cz sensors comparison
- at similar (high value) of threshold:
 - larger efficiency ~95% (n-gap and xdpw) vs 85% (std)



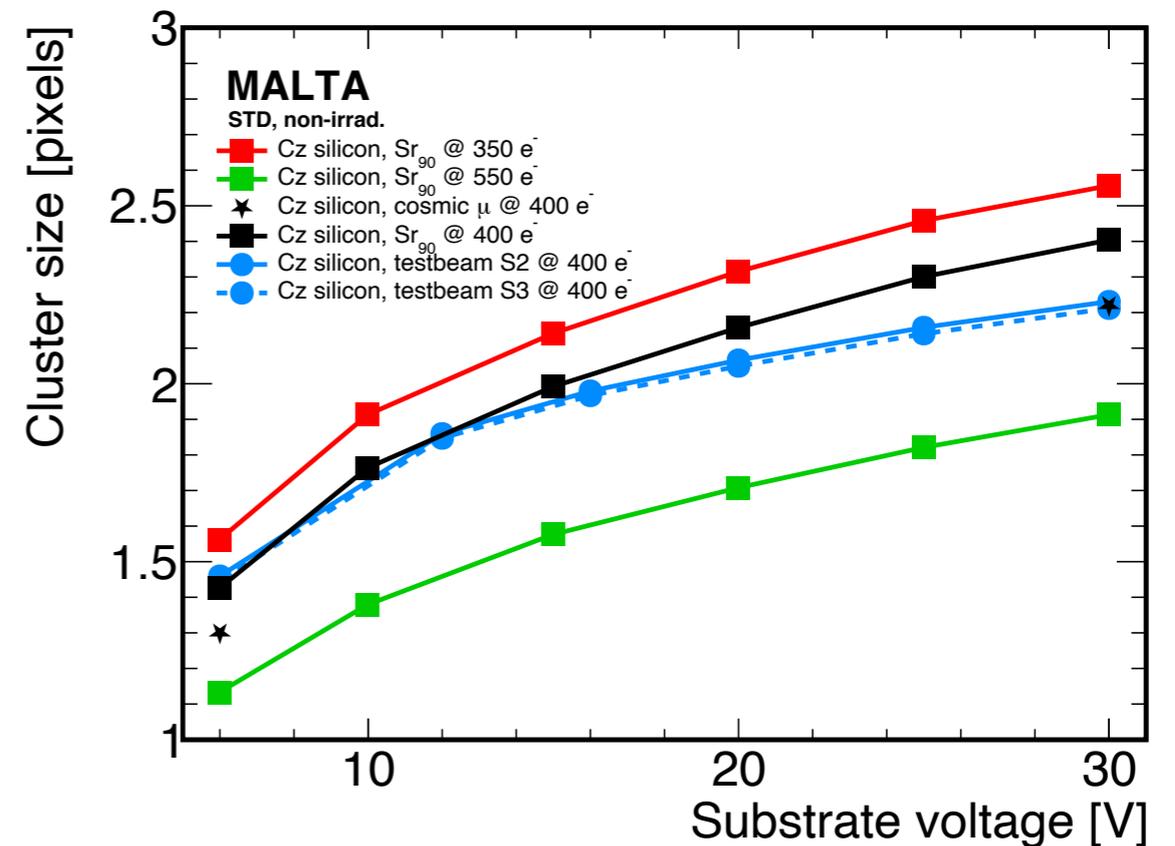
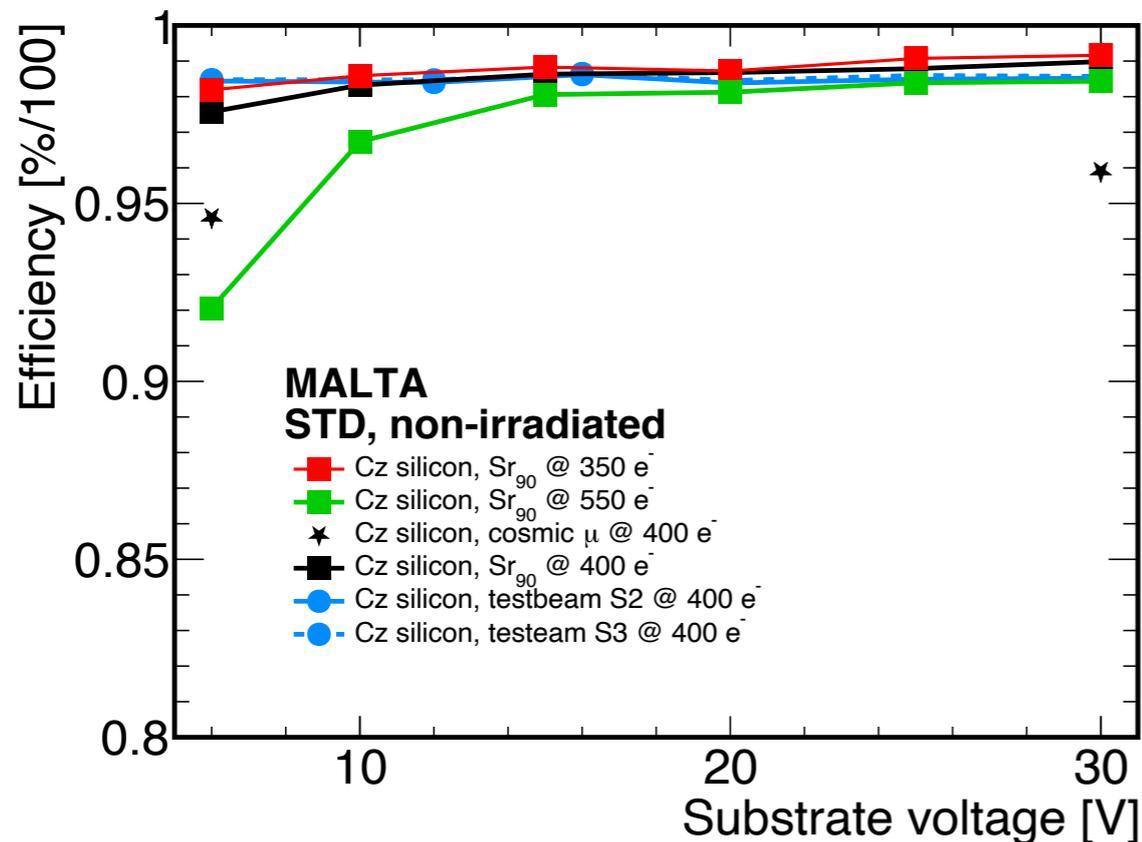
MALTA telescope 2020

- telescope for lab measurements
- 4 MALTA planes and one PMT
- PicoTDC for timing measurements
- different runs:
 - cosmic muons: high resolution but very low rate $1\mu/6'$
 - low energy electrons Sr-90: high rate but high multiple scattering
- entire telescope in a cold box
- powerful setup to test new chips
- development of DAQ, DQ and trigger logic for future testbeam



MALTA lab measurements

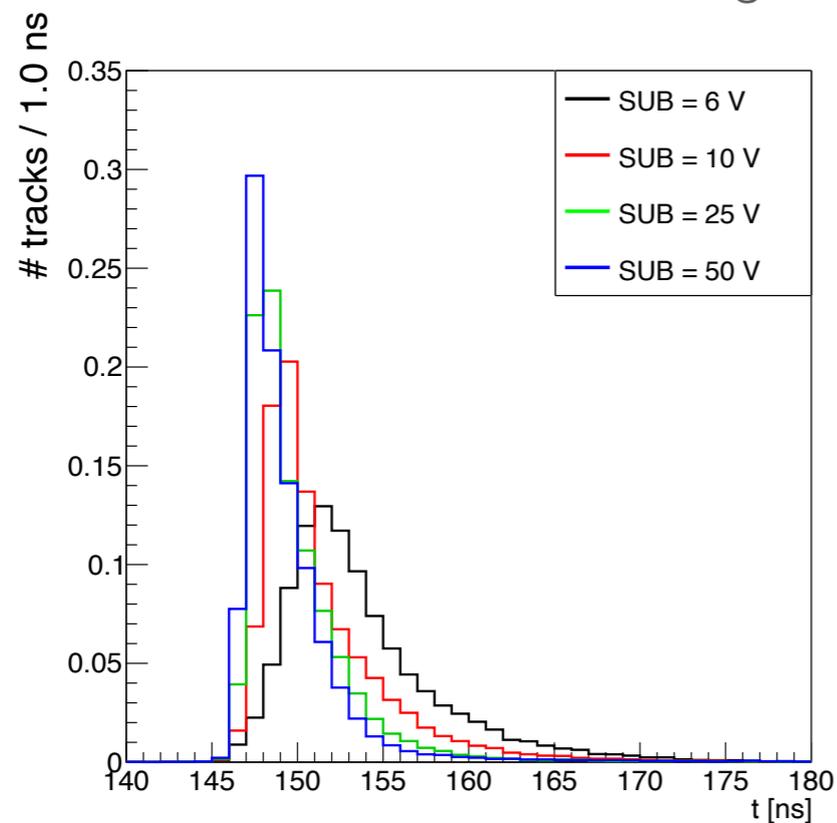
- measurement of efficiency and cluster size with cosmic muons and Sr-90
- good behavioural agreement with the testbeam, difference due to:
 - “beam” condition (testbeam $\sim 3\text{GeV } e^-$ vs Sr-90 $\sim 2\text{-}3\text{ MeV } e^-$)
 - not perfect alignment for μ



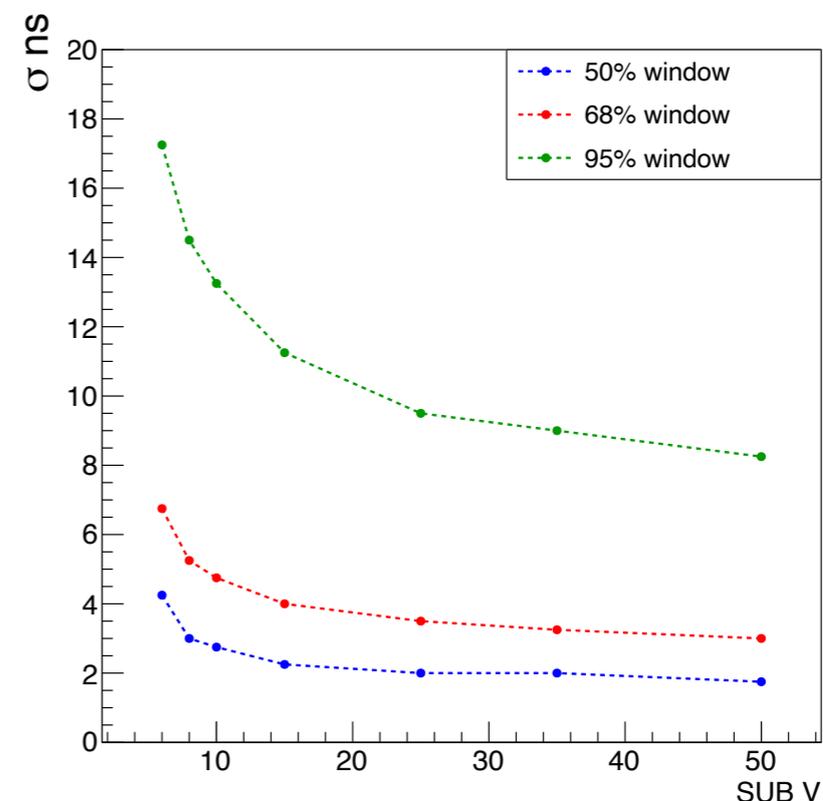
MALTA timing measurements

- PicoTDC used to measure Δt ($t_{\text{MALTA}} - t_{\text{PMT}}$): time of the fastest hit of the cluster (matched with the track in the DUT) - time of the hit in the scintillator $\sigma_{\text{PMT}} \sim 1$ ns (not subtracted)
- study the dependency of Δt as a function of substrate voltage and threshold
- define 3 integral windows which contain the 50%-68%-95% of the Δt distribution

time distribution is narrower at higher sub

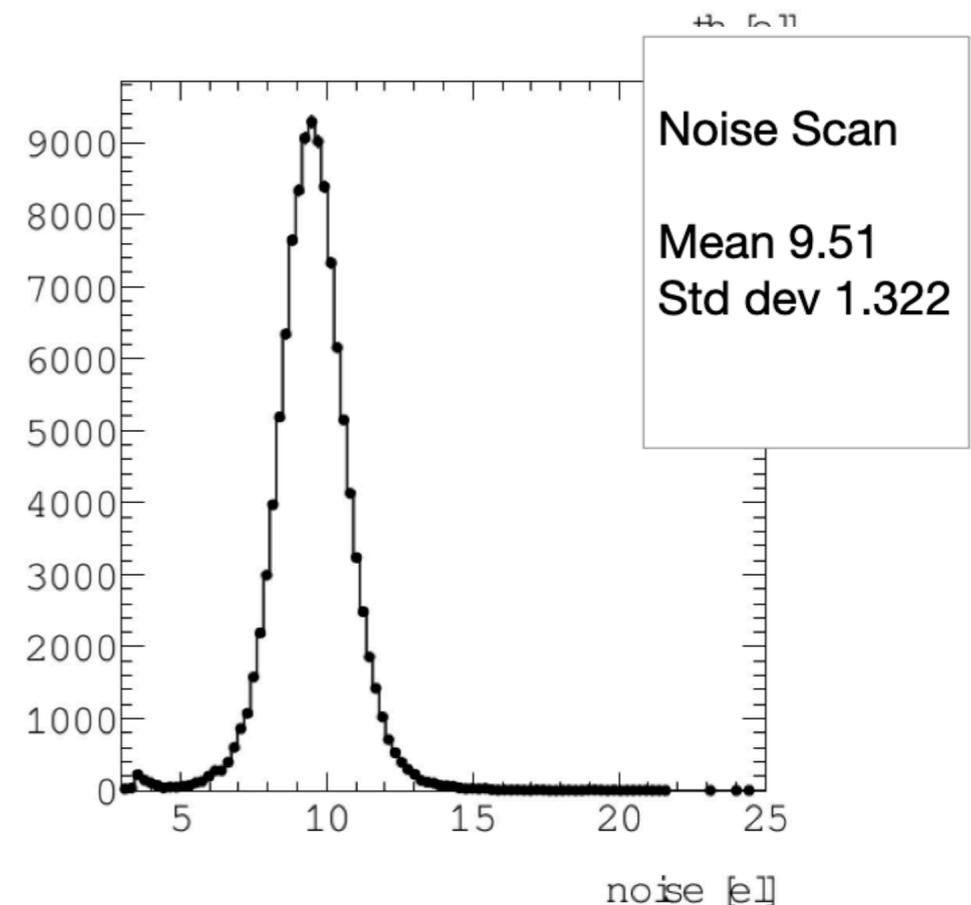
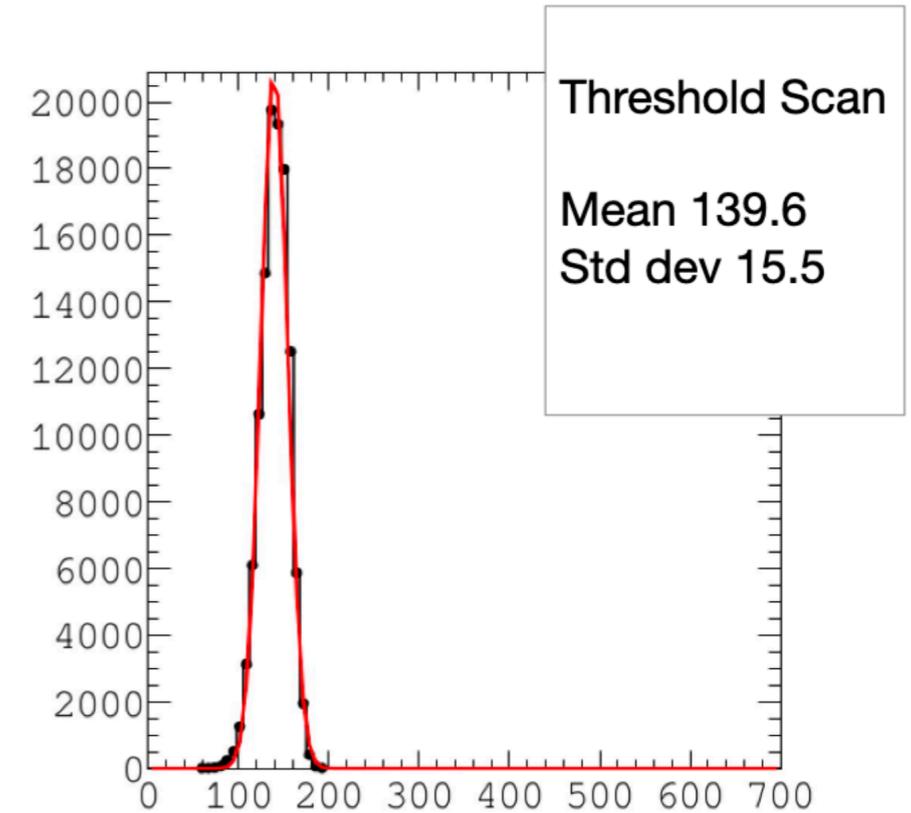
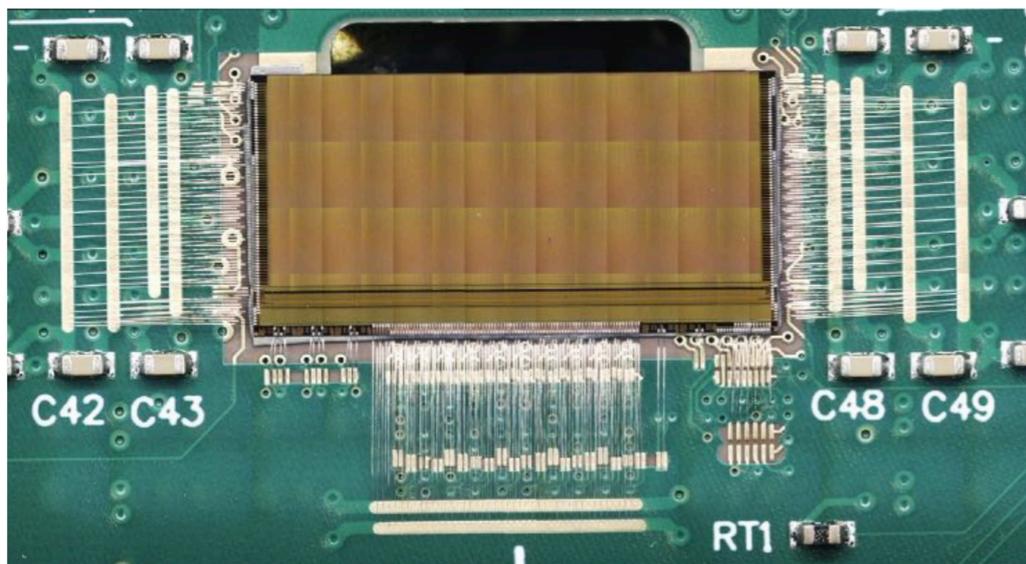


50% of the hits arrive within 2 ns above 15 V



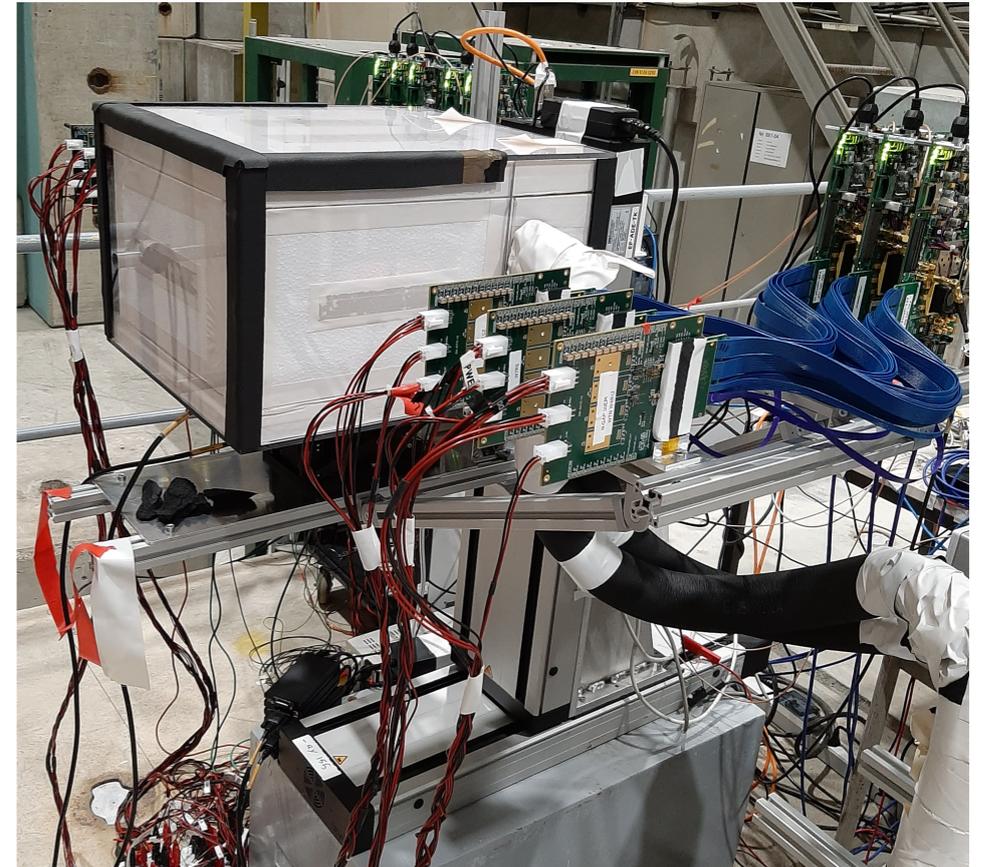
MALTA 2

- returned from foundry in Jan 2021
- 20.2x10.1 mm² sensor about half size of MALTA
- matrix of 224x512 pixels of 36.4 μm size
- faster analog front-end improves time resolution (larger transistors and the additional cascoded transistor)
- enlarged transistors as implemented in Mini-MALTA
- applying all the knowledge learnt from previous prototypes



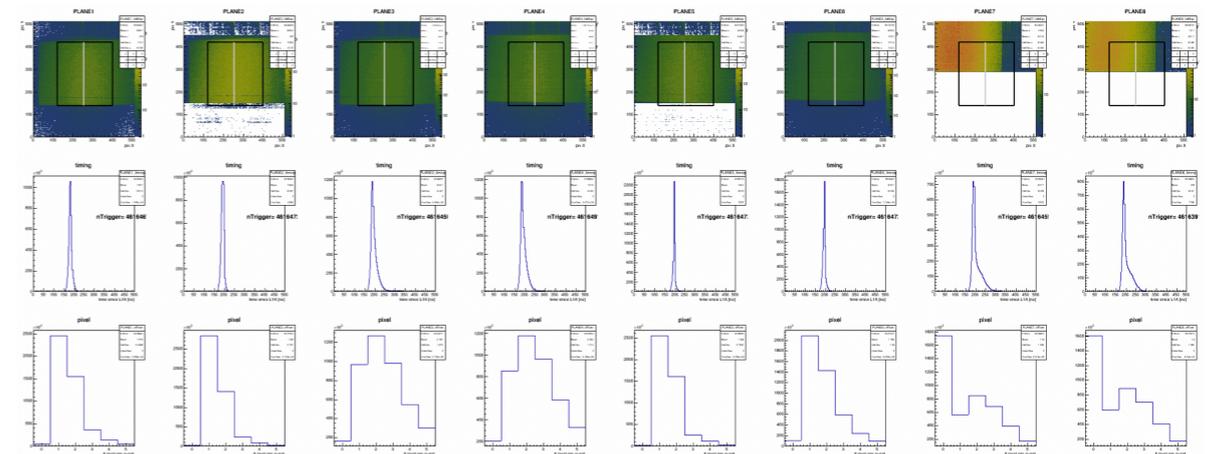
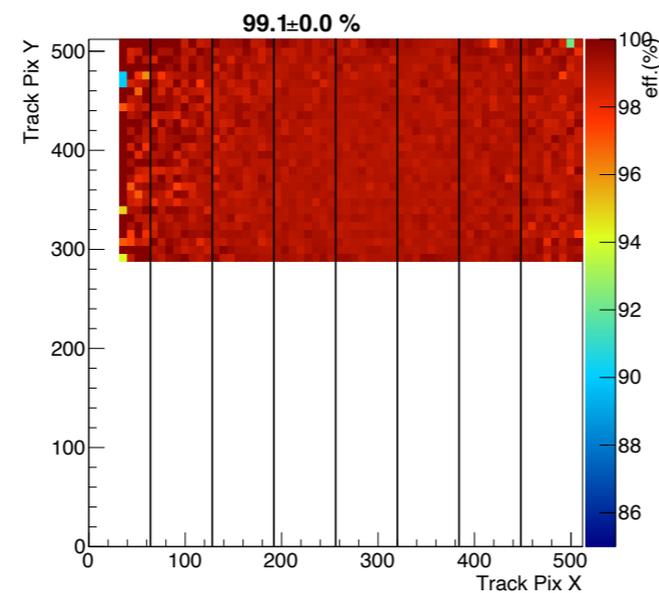
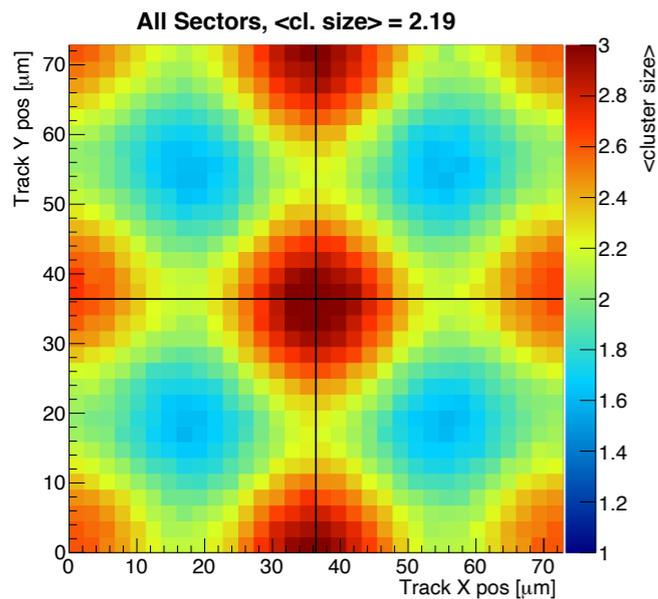
MALTA testbeam 2021

- test beam efforts at SPS CERN ongoing
- goal: dedicated to demonstrate MALTA2 performance in terms of radiation hardness ($> 10^{15}$ MeV Neq/cm²) and timing performance



MALTA Cz std -50V unirradiated

MALTA2 -6V unirradiated



conclusions

- development of the MALTA CMOS pixel sensors (TowerJazz 180 nm technology)
- MALTA very efficient after neutron irradiation (up to 2×10^{15} n_{eq}/cm^2)
- continue integrating MALTA in performing telescope systems
- more results from DESY 2019 test beam still to come
- testbeam @SPS in 2021: taking data results will come out soon

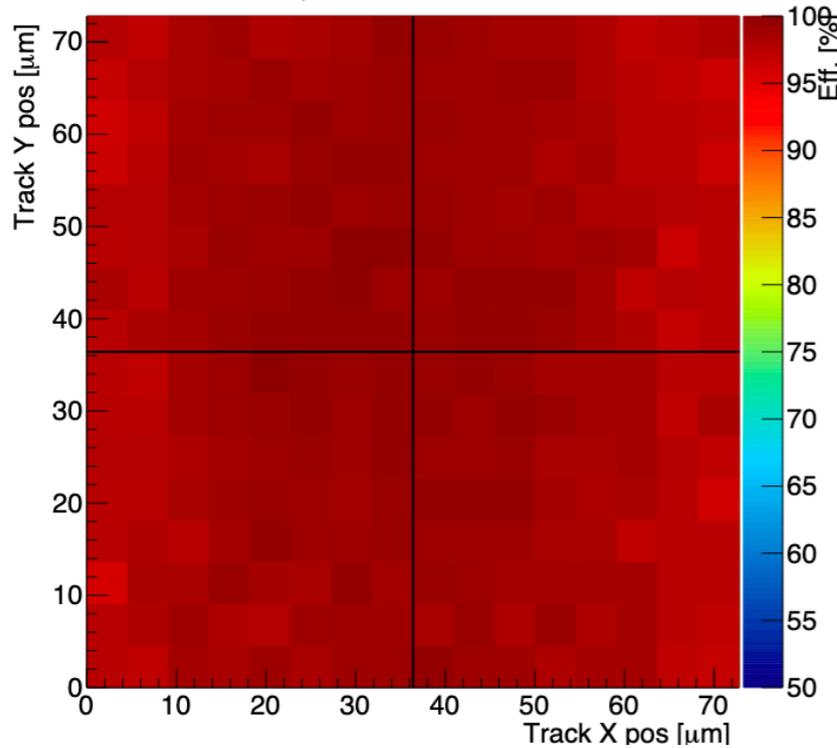
extra slides

In-pixel efficiency

**MALTA Cz
unirradiated**

$\epsilon = 98.5\%$

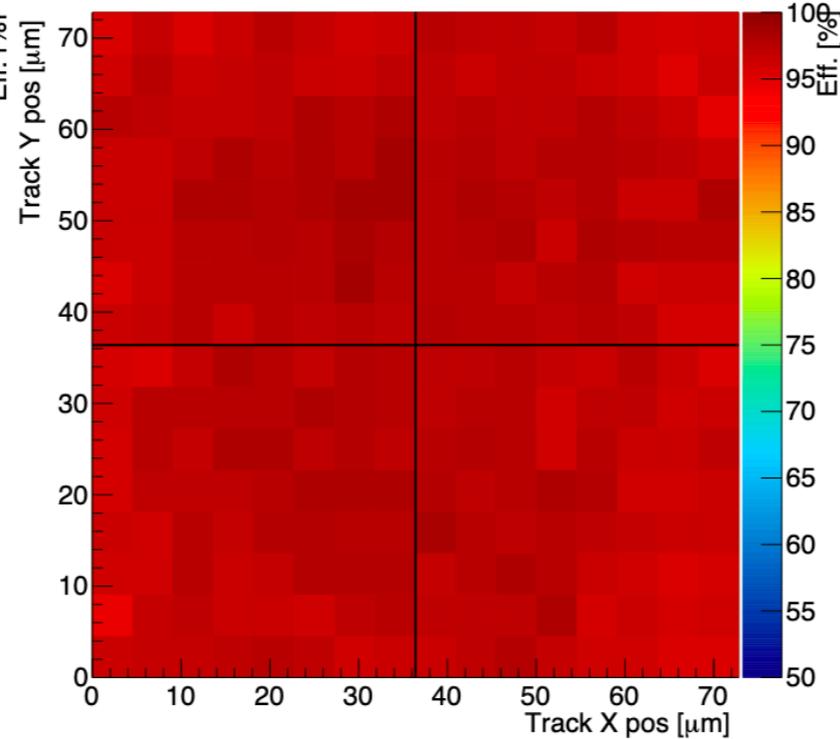
Sector 2, $\langle \text{eff} \rangle = 98.5 \pm 0.0 \%$



**MALTA Cz n-gap
 $1 \times 10^{15} n_{\text{eq}}/\text{cm}^2$**

$\epsilon = 97.0\%$

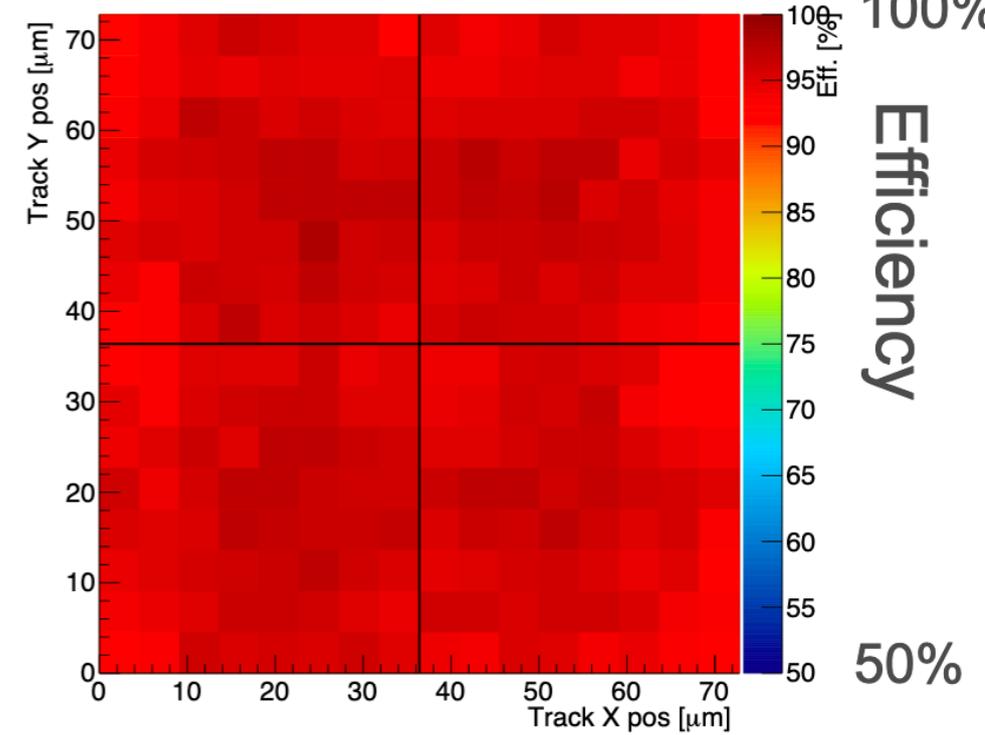
Sector 2, $\langle \text{eff} \rangle = 97.0 \pm 0.0 \%$



**MALTA Cz n-gap
 $2 \times 10^{15} n_{\text{eq}}/\text{cm}^2$**

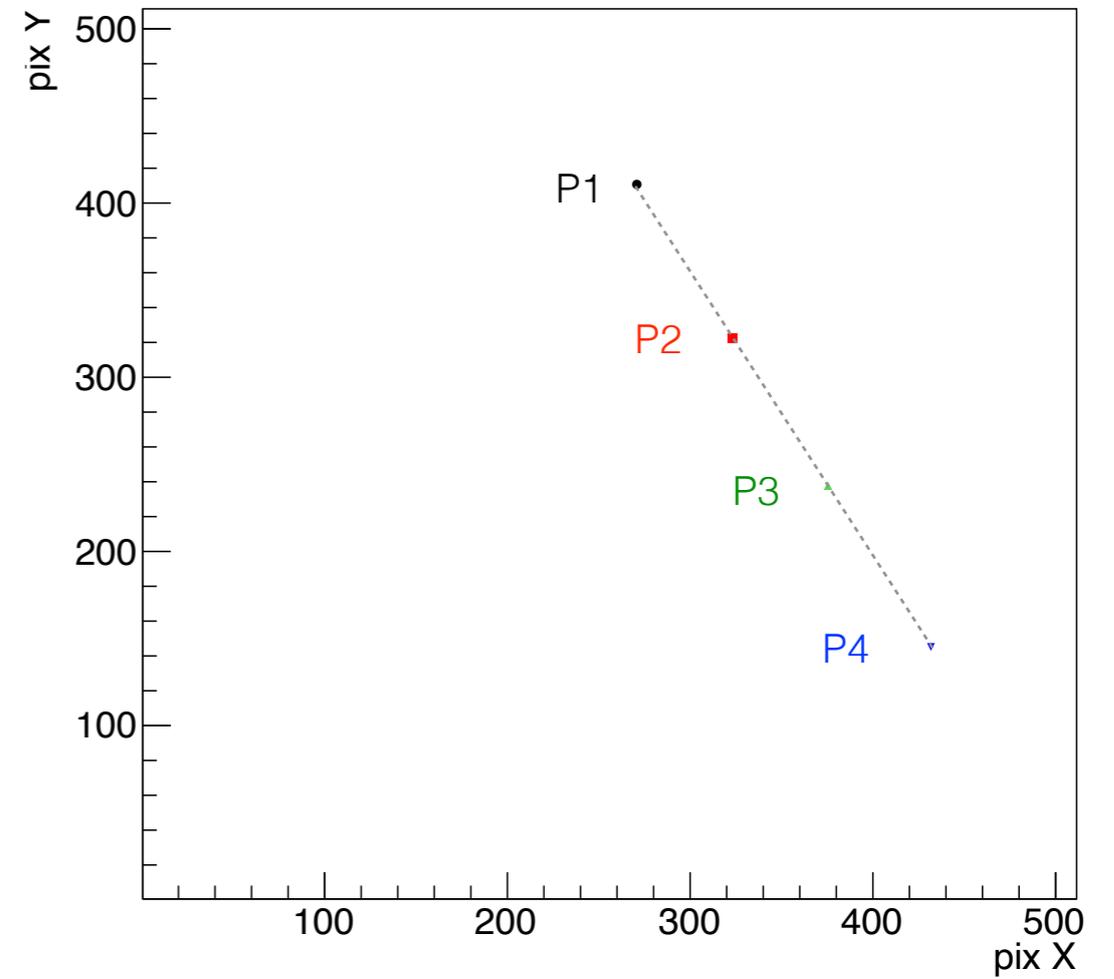
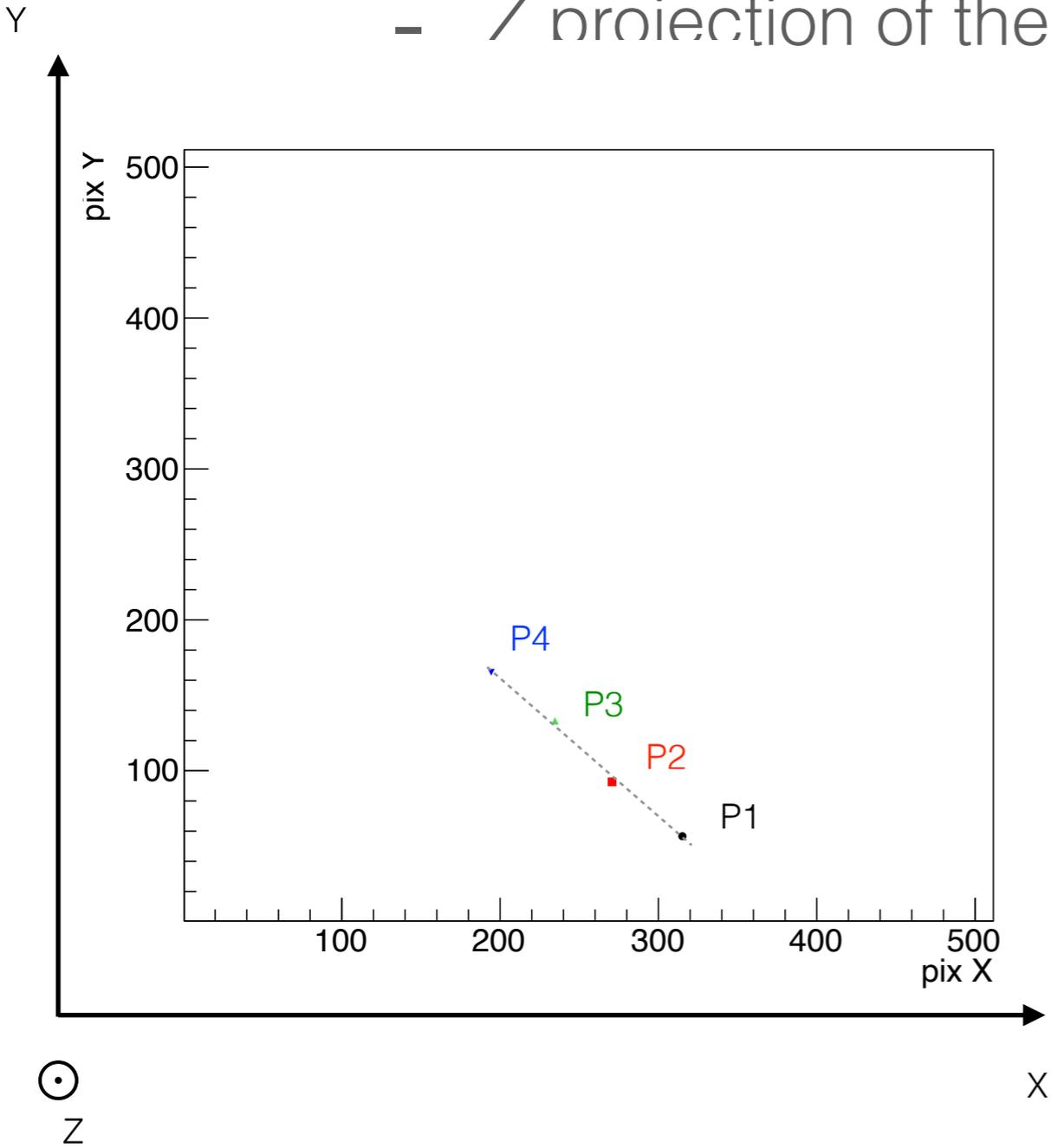
$\epsilon = 95.4\%$

Sector 2, $\langle \text{eff} \rangle = 95.4 \pm 0.0 \%$



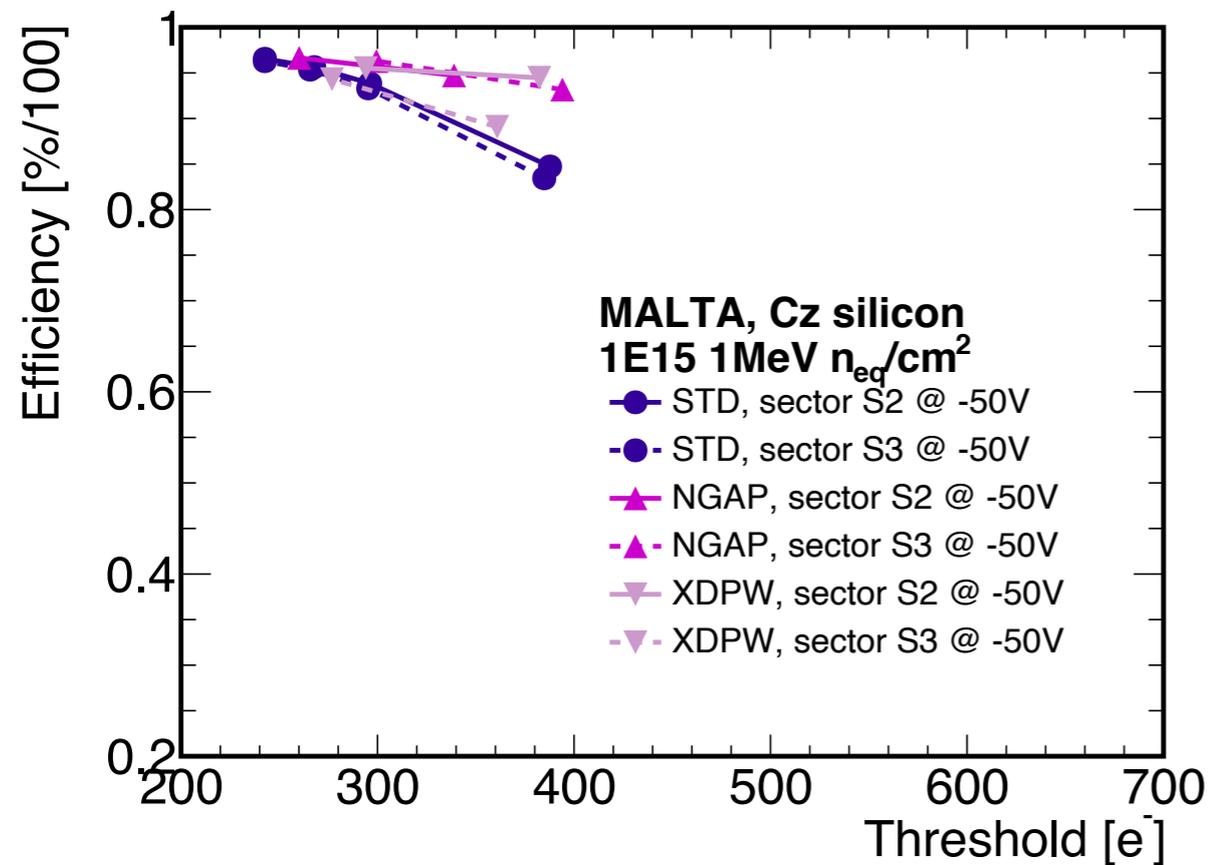
cosmic muon

- 7 projection of the 4 telescope planes

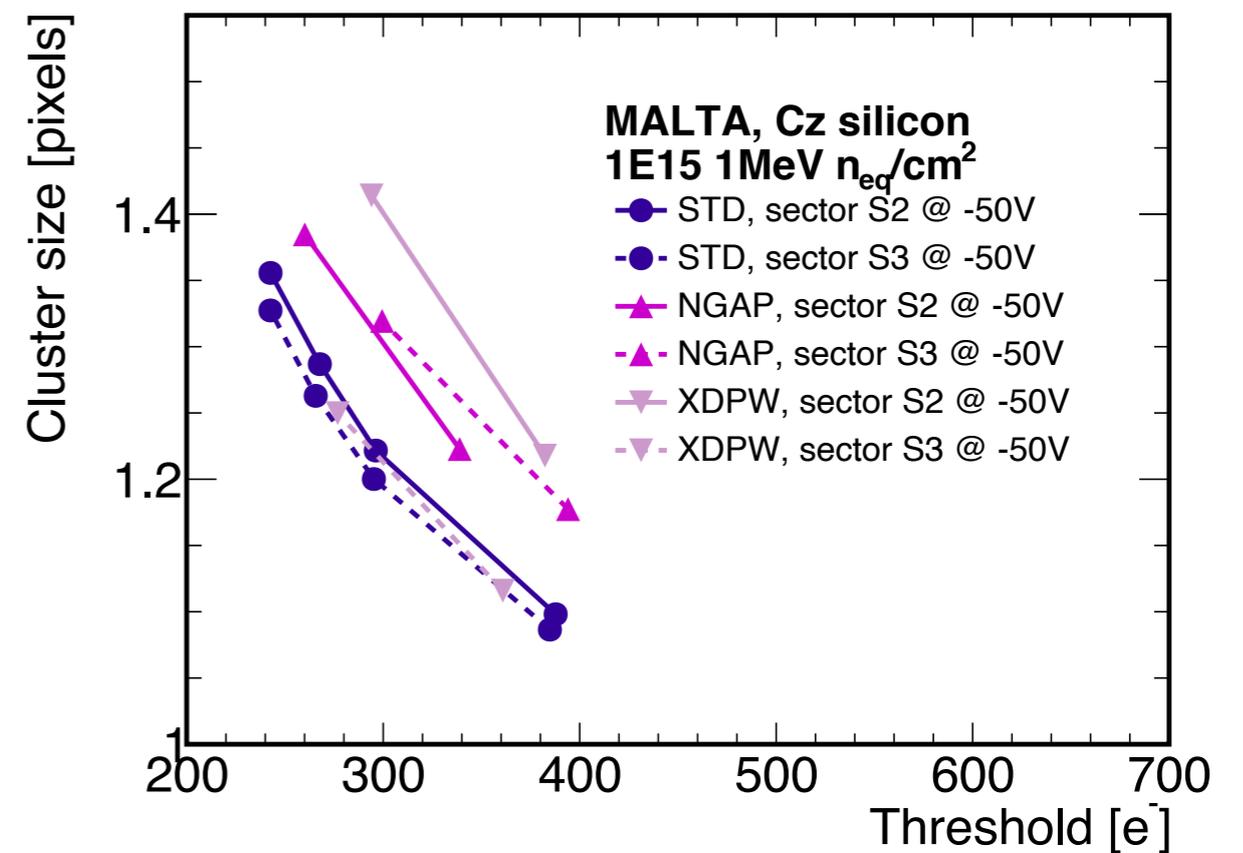


Cz irradiated chips

efficiency vs threshold

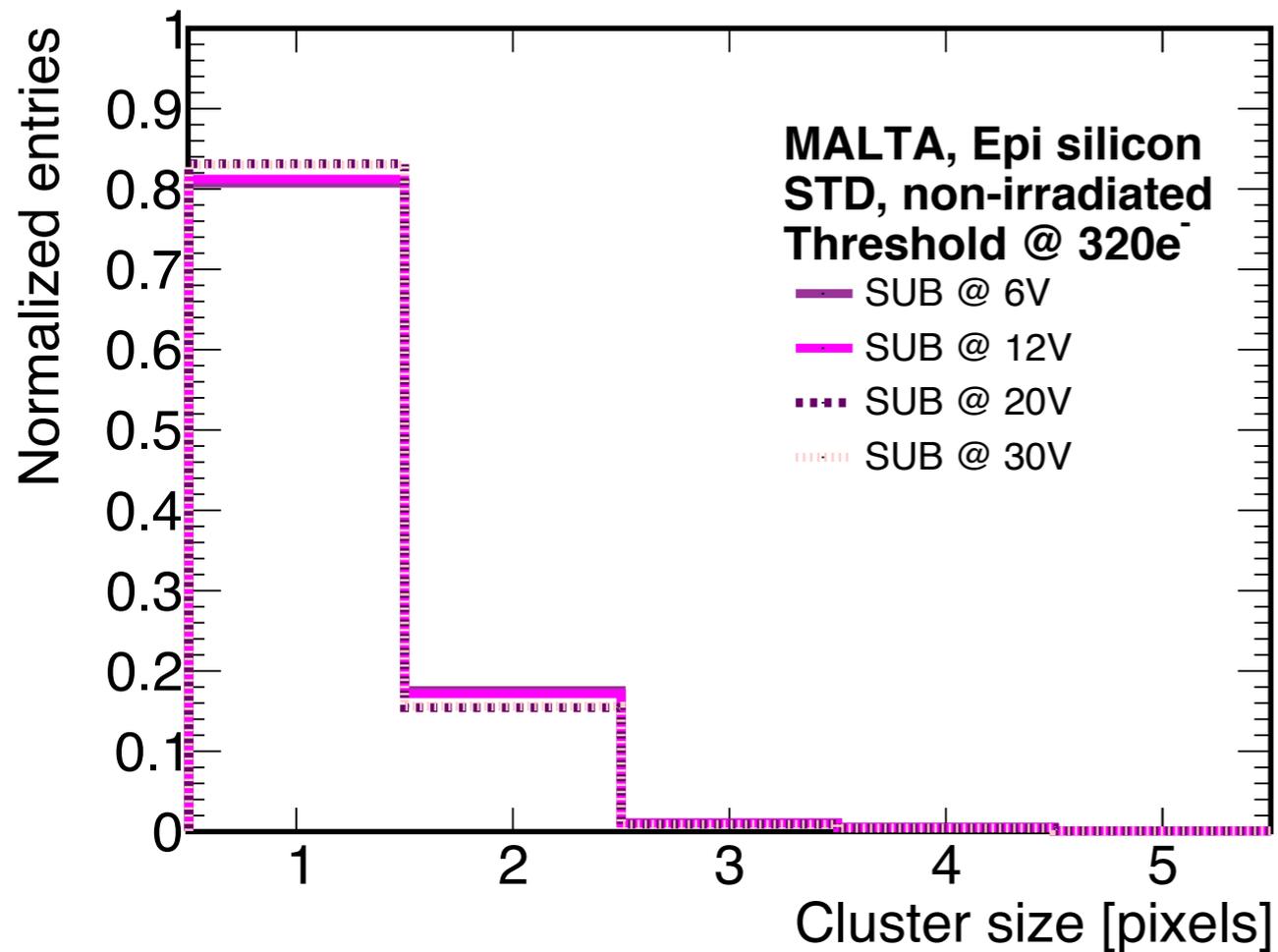


cluster size vs threshold

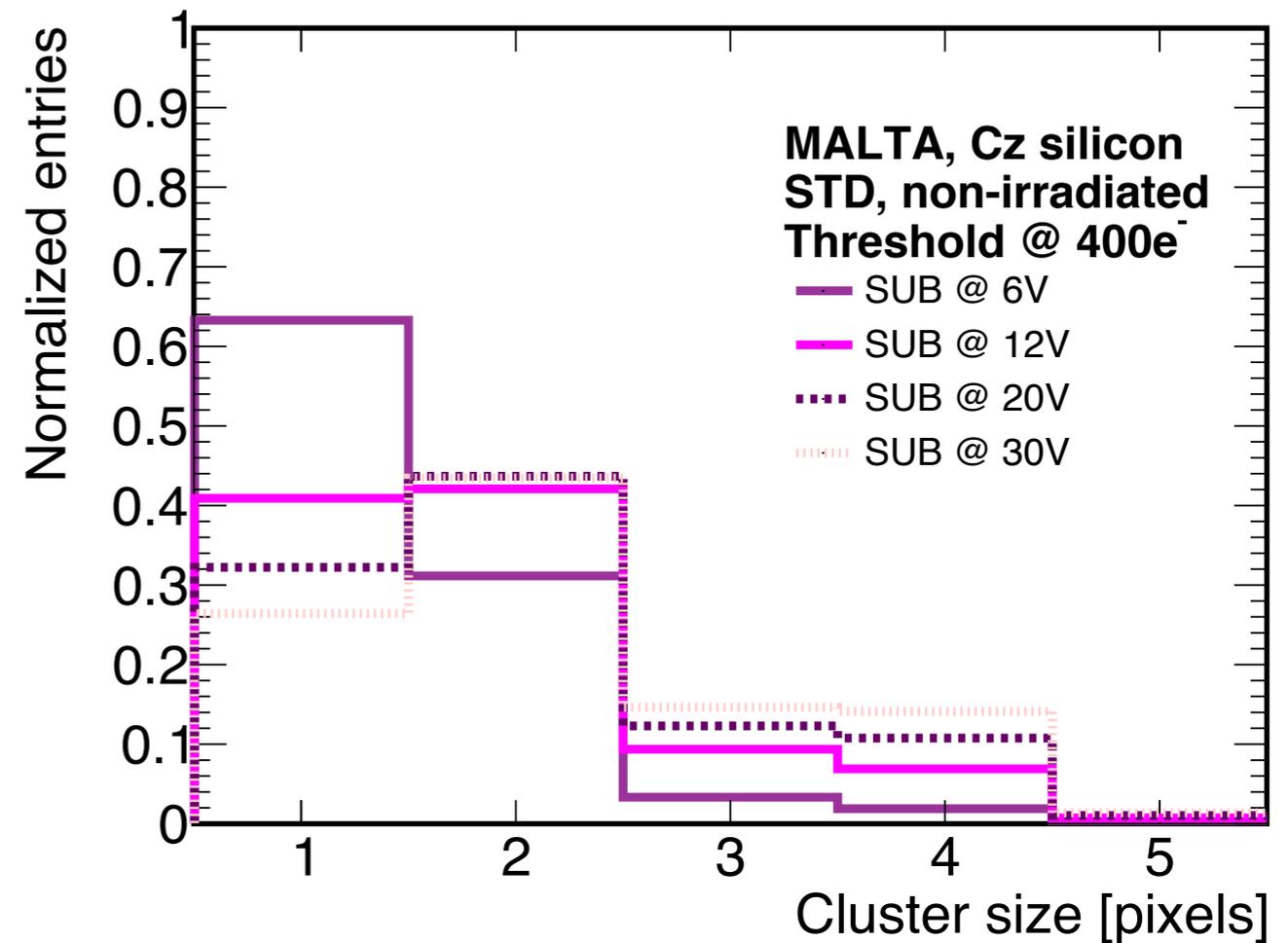


non irradiated chips

std Epi silicon



std Cz silicon



MALTA history 2

